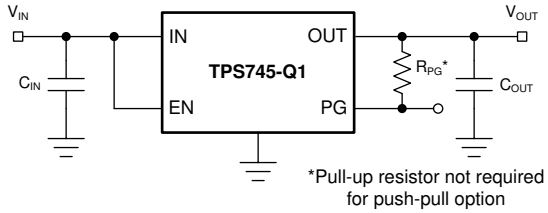
# TPS745-Q1 Automotive, 500-mA LDO With Power-Good in Small Wettable Flank WSON Packages

## 1 Features

- AEC-Q100 qualified for automotive applications:
  - Temperature grade 1: –40°C to +125°C, $T_A$
- Device junction temperature: –40°C to 150°C
- Package:
  - 2-mm × 2-mm wettable flank WSON
  - 3-mm × 3-mm wettable flank VSON
- Input voltage range: 1.5 V to 6.0 V
- Output voltage range:
  - Fixed option: 0.65 V to 5.0 V
  - Adjustable option: 0.55 V to 5.5 V
- High PSRR: 45 dB at 100 kHz
- Output accuracy: ±0.85% (25°C), ±1.5% maximum
- Power-good output options:
  - Open-drain and push-pull
- Ultra-low dropout:
  - 160 mV (max) at 500 mA (3.3 $V_{OUT}$)
- Stable with a 1-µF or larger capacitor
- Low $I_Q$: 25 µA (typical), 1.5 µA (shutdown)
- Active output discharge
- Functional Safety-Capable
  - Documentation available to aid functional safety system design
- Low thermal resistance:
  - DRV (6-pin WSON), $R_{\theta JA}$ = 80.3°C/W
  - DRB (8-pin VSON), $R_{\theta JA}$ = 55.5°C/W

## 2 Applications

- Automotive head units
- Front and rear cameras
- Automotive cluster displays
- Telematics control units
- Medium, short range radar




**Typical Application: Fixed Voltage Version**

## 3 Description

The TPS745-Q1 is a 500-mA ultra-low-dropout regulator (LDO) with power-good functionality. This device is available in a small 6-pin, 2-mm × 2-mm WSON package and a small 8-pin, 3-mm × 3-mm VSON package with wettable flanks to facilitate optical inspection. The TPS745-Q1 consumes low quiescent current and provides fast line and load transient performance.

The TPS745-Q1 is a flexible device for post-regulation by supporting an input voltage range from 1.5 V to 6.0 V and an externally adjustable output range of 0.55 V to 5.5 V. The device also features fixed output voltages for powering common voltage rails.

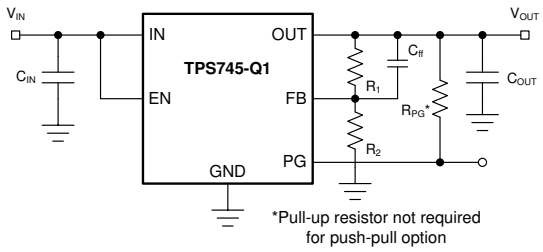
The TPS745-Q1 has a power-good (PG) output that monitors the voltage at the feedback pin to indicate the status of the output voltage. The EN input and PG output can be used for sequencing multiple power supplies in the system.

The TPS745-Q1 is stable with small ceramic output capacitors, allowing for a small overall solution size. A precision band-gap and error amplifier provides high accuracy of ±0.85% (max) at 25°C and ±1.5% (max) over temperature. This device includes integrated thermal shutdown, current limit, and undervoltage lockout (UVLO) features. The TPS745-Q1 has an internal foldback current limit that helps reduce the thermal dissipation during short-circuit events.

**Device Information**(1)

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|---|---|---|
| TPS745-Q1 | Wettable flank WSON (6) | 2.00 mm × 2.00 mm |
| | Wettable flank VSON (8) | 3.00 mm × 3.00 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.




**Typical Application: Adjustable Voltage Version**

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision B (January 2021) to Revision C (May 2022) | Page |
|---|---|
| • Changed DRB $R_{\theta JA}$ from *62.0°C/W* to *55.5°C/W* and added Functional Safety Bullet | 1 |
| • Changed *WSON* to *VSON* for DRB package throughout document | 1 |
| • Updated thermal table to reflect correct values and package name | 5 |

| Changes from Revision A (October 2019) to Revision B (January 2021) | Page |
|---|---|
| • Changed DRB package from preview to production data | 1 |
| • Added limits to $I_{SC}$ and $t_{STR}$ | 5 |
| • Changed $V_{DO}$ and $V_{OL(PG)}$ conditions to correct values | 5 |


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## 5 Pin Configuration and Functions

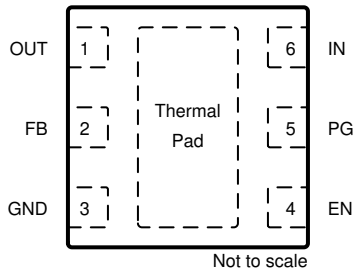



**Figure 5-1. DRV Package, 6-Pin Adjustable WSON (Top View)**

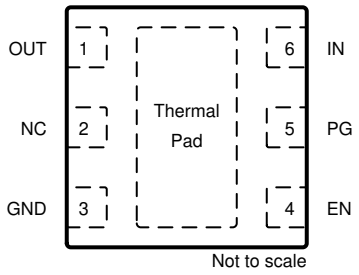



**Figure 5-2. DRV Package, 6-Pin Fixed WSON (Top View)**

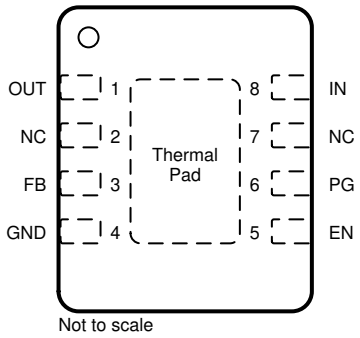



**Figure 5-3. DRB Package, 8-Pin Adjustable VSON (Top View)**

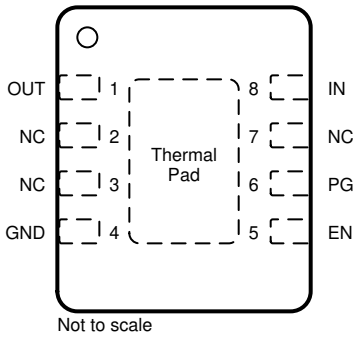



**Figure 5-4. DRB Package, 8-Pin Fixed VSON (Top View)**

**Table 5-1. Pin Functions**

| PIN | | | | | I/O | DESCRIPTION |
|---|---|---|---|---|---|---|
| NAME | DRV (Fixed) | DRV (Adjust) | DRB (Fixed) | DRB (Adjust) | | |
| EN | 4 | 4 | 5 | 5 | Input | Enable pin. Drive EN greater than $V_{EN(HI)}$ to turn on the regulator. Drive EN less than $V_{EN(LO)}$ to put the low-dropout regulator (LDO) into shutdown mode. |
| FB | — | 2 | — | 3 | — | This pin is used as an input to the control loop error amplifier and is used to set the output voltage of the LDO. |
| GND | 3 | 3 | 4 | 4 | — | Ground pin. |
| IN | 6 | 6 | 8 | 8 | Input | Input pin. For best transient response and to minimize input impedance, use the recommended value or larger ceramic capacitor from IN to ground as listed in the *Recommended Operating Conditions* table and the *Input and Output Capacitor Selection* section. Place the input capacitor as close to the output of the device as possible. |
| NC | 2 | — | 2, 3, 7 | 2, 7 | — | No internal connection. Ground this pin for better thermal performance. |
| OUT | 1 | 1 | 1 | 1 | Output | Regulated output voltage pin. A capacitor is required from OUT to ground for stability. For best transient response, use the nominal recommended value or larger ceramic capacitor from OUT to ground; see the *Recommended Operating Conditions* table and the *Input and Output Capacitor Selection* section. Place the output capacitor as close to output of the device as possible. |
| PG | 5 | 5 | 6 | 6 | Output | Power-good output. Available in open-drain and push-pull topologies. A pullup resistor is only required for the open-drain type. For the open-drain version, if the power-good functionality is not being used, ground this pin or leave floating. For the push-pull version, if the power-good functionality is not being used, leave this pin floating. |
| Thermal Pad | | | | | — | The thermal pad is electrically connected to the GND node. Connect to the GND plane for improved thermal performance. |

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# 6 Specifications

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

| | | MIN | MAX | UNIT |
|---|---|---|---|---|
| Voltage | Supply, $V_{IN}$ | –0.3 | 6.5 | V |
| | Enable, $V_{EN}$ | –0.3 | 6.5 | |
| | Feedback, $V_{FB}$ | –0.3 | 2.0 | |
| | Power-good, $V_{PG}$ | –0.3 | 6.5 | |
| | Output, $V_{OUT}$ | –0.3 | $V_{IN}$ + 0.3(2) | |
| Current | Output, $I_{OUT}$ | Internally limited | | |
| | Power-good, $I_{PG}$ | | ±10 | mA |
| Temperature | Operating junction, $T_J$ | –40 | 150 | °C |
| | Storage, $T_{stg}$ | –65 | 150 | |

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The absolute maximum rating is $V_{IN}$ + 0.3 V or 6.0 V, whichever is smaller.

## 6.2 ESD Ratings

| | | | VALUE | UNIT |
|---|---|---|---|---|
| $V_{(ESD)}$ | Electrostatic discharge | Human-body model (HBM), per AEC Q100-002(1) | ±2000 | V |
| | | Charged-device model (CDM), per AEC Q100-011, corner pins | ±750 | |
| | | Charged-device model (CDM), per AEC Q100-011, other pins | ±500 | |

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | NOM | MAX | UNIT |
|---|---|---|---|---|---|---|
| $V_{IN}$ | Input voltage | | 1.5 | | 6.0 | V |
| $V_{OUT}$ | Output voltage | Adjustable only | 0.55 | | 5.5 | V |
| | | Fixed only | 0.65 | | 5.0 | |
| $I_{OUT}$ | Output current | | 0 | | 500 | mA |
| $C_{IN}$ | Input capacitor | | 1 | | | µF |
| $C_{OUT}$ | Output capacitor(1) | | 1 | | 220 | µF |
| $C_{FF}$ | Feed-forward capacitor | | | 10 | | nF |
| $V_{EN}$ | Enable voltage | | 0 | | 6.0 | V |
| $f_{EN}$ | Enable toggle frequency | | | | 10 | kHz |
| $V_{PG}$ | PG voltage | | 0 | | 6.0 | V |
| $T_J$ | Junction operating temperature | | –40 | | 150 | °C |

(1) Minimum derated capacitance of 0.47 µF is required for stability.


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## 6.4 Thermal Information

| THERMAL METRIC[1] | | TPS745-Q1 | | UNIT |
|---|---|---|---|---|
| | | DRV (WSON) | DRB (VSON) | |
| | | 6 PINS | 8 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 80.3 | 55.5 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 98.7 | 70.7 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 44.8 | 28.0 | °C/W |
| $\psi_{JT}$ | Junction-to-top characterization parameter | 6.1 | 4.3 | °C/W |
| $\psi_{JB}$ | Junction-to-board characterization parameter | 45.0 | 28.0 | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | 20.8 | 10.2 | °C/W |

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

## 6.5 Electrical Characteristics

at operating temperature range ($T_J$ = –40°C to +150°C), $V_{IN}$ = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $V_{EN}$ = $V_{IN}$, and $C_{IN}$ = $C_{OUT}$ = 1 µF, unless otherwise noted; all typical values are at $T_J$ = 25°C

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|---|
| $V_{FB}$ | Feedback voltage | Adjustable only | | | 0.55 | | V |
| | Output accuracy[1] | $T_J$ = 25°C | | –0.85% | | 0.85% | |
| | | -40°C ≤ $T_J$ ≤ 85°C | | –1.00% | | 1.00% | |
| | | -40°C ≤ $T_J$ ≤ 150°C | | –1.50% | | 1.50% | |
| | Line regulation | $V_{OUT(NOM)}$ + 0.5 V[2] ≤ $V_{IN}$ ≤ 6.0 V | | | 2 | 7.5 | mV |
| | Load regulation | 0.1 mA ≤ $I_{OUT}$ ≤ 500 mA, $V_{IN}$ ≥ 2.0 V | | | 0.030 | | V/A |
| $I_{GND}$ | Ground current | $I_{OUT}$ = 0 mA | $T_J$ = 25°C | | 25 | 32 | µA |
| | | | -40°C ≤ $T_J$ ≤ 150°C | | 25 | 36 | |
| $I_{SHDN}$ | Shutdown current | $V_{EN}$ ≤ 0.3 V, 1.5 V ≤ $V_{IN}$ ≤ 6.0 V | -40°C ≤ $T_J$ ≤ 125°C | | 0.1 | 1 | µA |
| | | | -40°C ≤ $T_J$ ≤ 150°C | | 0.1 | 1.55 | |
| $I_{FB}$ | Feedback pin current | Adjustable only | | | 0.01 | 0.1 | µA |
| $I_{CL}$ | Output current limit | $V_{OUT(NOM)}$ < 1.0 V, $V_{OUT}$ = $V_{OUT(NOM)}$ - 0.2 V, $V_{IN}$ = 2.0 V | | 515 | 720 | 865 | mA |
| | | $V_{OUT(NOM)}$ ≥ 1.0 V, $V_{OUT}$ = $V_{OUT(NOM)}$ x 0.85, $V_{IN}$ = $V_{OUT(NOM)}$ + 1.0 V | | | | | |
| $I_{SC}$ | Short-circuit current limit | $V_{OUT}$ = 0 V | $V_{OUT(NOM)}$ < 1.0 V, $V_{IN}$ = 2.0 V | 200 | 350 | 400 | mA |
| | | | $V_{OUT(NOM)}$ ≥ 1.0 V, $V_{IN}$ = $V_{OUT(NOM)}$ + 1.0 V | | | | |
| $V_{DO}$ | Dropout voltage | $I_{OUT}$ = 500 mA, $V_{OUT}$ = 0.95 × $V_{OUT(NOM)}$ | 0.65 V ≤ $V_{OUT}$ < 0.8 V[3] | | 720 | 910 | mV |
| | | | 0.8 V ≤ $V_{OUT}$ < 1.0 V | | 585 | 780 | |
| | | | 1.0 V ≤ $V_{OUT}$ < 1.2 V | | 420 | 600 | |
| | | | 1.2 V ≤ $V_{OUT}$ < 1.5 V | | 285 | 430 | |
| | | | 1.5 V ≤ $V_{OUT}$ < 1.8 V | | 180 | 265 | |
| | | | 1.8 V ≤ $V_{OUT}$ < 2.5 V | | 140 | 215 | |
| | | | 2.5 V ≤ $V_{OUT}$ < 3.3 V | | 105 | 170 | |
| | | | 3.3 V ≤ $V_{OUT}$ ≤ 5.5 V | | 95 | 160 | |
| PSRR | Power-supply rejection ratio | $V_{OUT}$ = 1.8 V, $V_{IN}$ = 2.8 V, $I_{OUT}$ = 500 mA, $C_{OUT}$ = 2.2 µF | f = 1 kHz | | 57 | | dB |
| | | | f = 100 kHz | | 42 | | |
| | | | f = 1 MHz | | 35 | | |
| $V_N$ | Output noise voltage | BW = 10 Hz to 100 kHz, $V_{OUT}$ = 0.9 V, $V_{IN}$ = 1.9 V | | | 53 | | $\mu V_{RMS}$ |
| $V_{UVLO}$ | Undervoltage lockout | $V_{IN}$ falling | | 1.17 | 1.30 | 1.42 | V |
| | | $V_{IN}$ rising | | 1.21 | 1.34 | 1.47 | |
| $V_{UVLO,HYST}$ | Undervoltage lockout hysteresis | $V_{IN}$ hysteresis | | | 40 | | mV |
| $t_{STR}$ | Startup time | From EN low-to-high transition to $V_{OUT}$ = $V_{OUT(NOM)}$ x 0.95 | | 200 | 500 | 650 | µs |

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## 6.5 Electrical Characteristics (continued)

at operating temperature range ($T_J$ = –40°C to +150°C), $V_{IN}$ = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $V_{EN}$ = $V_{IN}$, and $C_{IN}$ = $C_{OUT}$ = 1 µF, unless otherwise noted; all typical values are at $T_J$ = 25°C

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|
| $V_{EN(HI)}$ | EN pin high voltage (enabled) | | 1.0 | | | V |
| $V_{EN(LO)}$ | EN pin low voltage (disabled) | | | | 0.3 | V |
| $I_{EN}$ | Enable pin current | $V_{IN}$ = $V_{EN}$ = 6.0 V | | 10 | | nA |
| $R_{PULLDOWN}$ | Pulldown resistance | $V_{IN}$ = 6.0 V | | 95 | | Ω |
| $PG_{HTH}$ | PG high threshold | $V_{OUT}$ increasing | 89 | 92 | 96 | %$V_{OUT}$ |
| $PG_{LTH}$ | PG low threshold | $V_{OUT}$ decreasing | 86 | 90 | 93 | %$V_{OUT}$ |
| $PG_{HYST}$ | PG hysteresis | | | 2 | | %Vout |
| $V_{OL(PG)}$ | PG pin low-level output voltage | $V_{IN}$ ≥ 1.5V, $I_{SINK}$ = 1.0 mA | | | 300 | mV |
| | | $V_{IN}$ ≥ 2.75V, $I_{SINK}$ = 2.0 mA | | | | |
| $V_{OH(PG)}$ | PG pin high-level output voltage(4) | $V_{OUT}$ ≥ 1.0V, $I_{SOURCE}$ = 0.04 mA | 0.8 x $V_{OUT}$ | | | V |
| | | $V_{OUT}$ ≥ 1.4V, $I_{SOURCE}$ = 0.2 mA | | | | |
| | | $V_{OUT}$ ≥ 2.5V, $I_{SOURCE}$ = 0.5 mA | | | | |
| | | $V_{OUT}$ ≥ 4.5V, $I_{SOURCE}$ = 1.0 mA | | | | |
| $I_{lkg(PG)}$ | PG pin leakage current(5) | $V_{OUT}$ > $PG_{HTH}$, $V_{PG}$ = 6.0 V | | 7 | 50 | nA |
| $T_{SD}$ | Thermal shutdown | Shutdown, temperature increasing | | 170 | | °C |
| | | Reset, temperature decreasing | | 155 | | |

(1) When the device is connected to external feedback resistors at the FB pin, external resistor tolerances are not included.
(2) $V_{IN}$ = 1.5 V for $V_{OUT}$ < 1.0 V.
(3) Dropout is not tested for nominal output voltages below 0.65 V since the input voltage may be below UVLO.
(4) Push-pull version only. The push-pull option is supported only for $V_{OUT}$ ≥ 1.0 V.
(5) Open-drain version only.

## 6.6 Timing Requirements

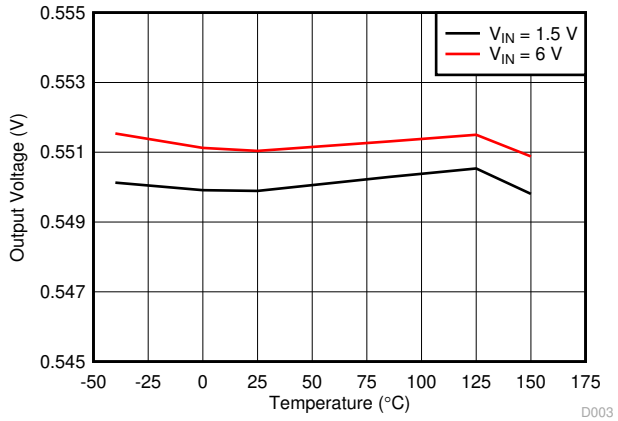
| Parameter | | | MIN | TYP | MAX | UNIT |
|---|---|---|---|---|---|---|
| $t_{PGDH}$ | PG delay time rising, time from 92% $V_{OUT}$ to 20% of PG(1) | | 135 | 165 | 178 | µs |
| | | 'B' version(2) | 4.5 | 5 | 5.5 | ms |
| $t_{PGDL}$ | PG delay time falling, time from 90% $V_{OUT}$ to 80% of PG(1) | | 1.5 | 7 | 10 | µs |

(1) Output overdrive = 10%.
(2) See the Device Nomenclature table for more information on available PG timings.


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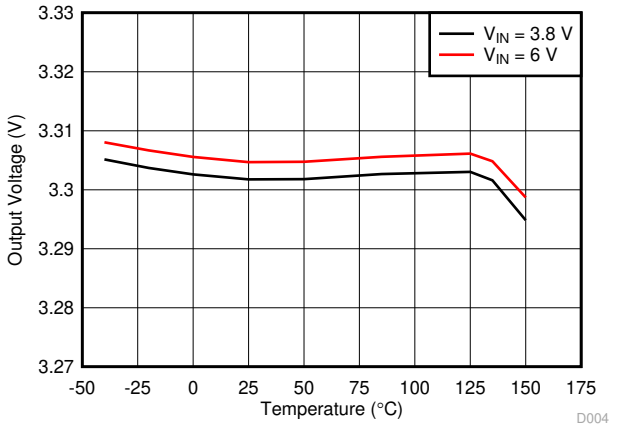
## 6.7 Typical Characteristics

at operating temperature range $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $V_{EN}$ = $V_{IN}$, and $C_{IN}$ = $C_{OUT}$ = 1 µF (unless otherwise noted)



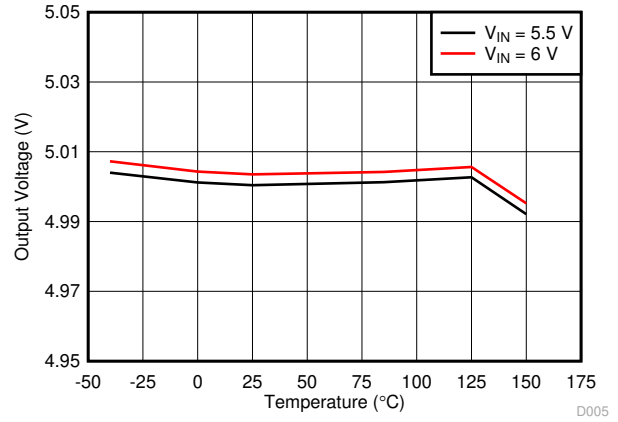

$V_{OUT}$ = 0.55 V, $I_{OUT}$ = 1 mA

**Figure 6-1. Output Voltage vs Ambient Temperature**



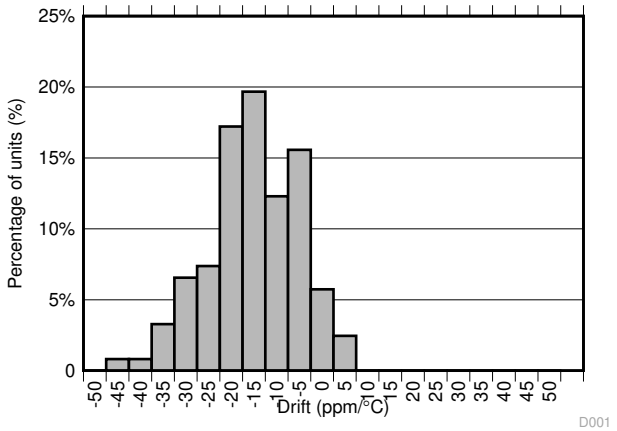

$V_{OUT}$ = 3.3 V, $I_{OUT}$ = 1 mA

**Figure 6-2. Output Voltage vs Ambient Temperature**



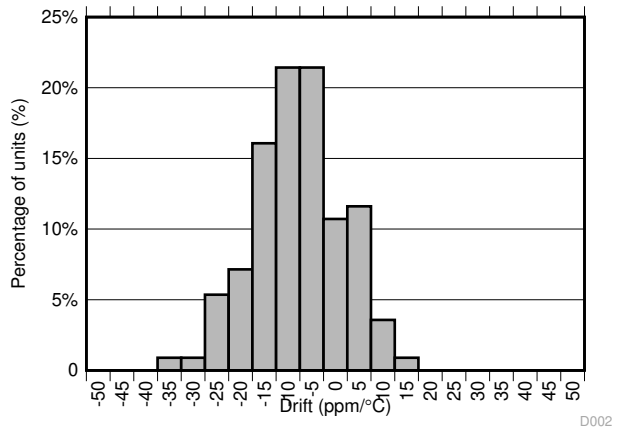

$V_{OUT}$ = 5 V, $I_{OUT}$ = 1 mA

**Figure 6-3. Output Voltage vs Ambient Temperature**



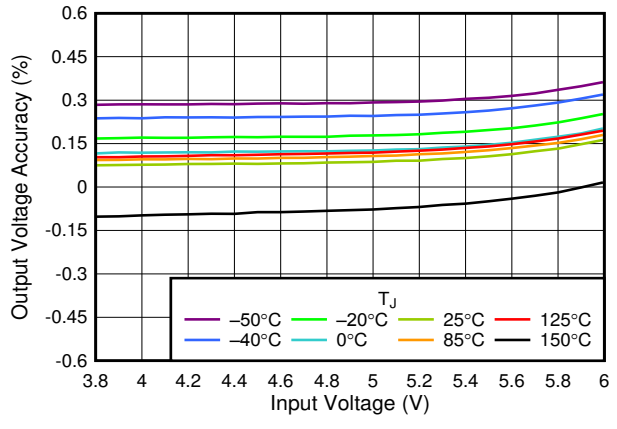

0.65-V, 3.3-V, and 5-V options, $I_{OUT}$ = 1 mA

**Figure 6-4. Temperature Drift Histogram (–40°C to +25°C)**




0.65-V, 3.3-V, and 5-V options, $I_{OUT}$ = 1 mA

**Figure 6-5. Temperature Drift Histogram (25°C to 150°C)**



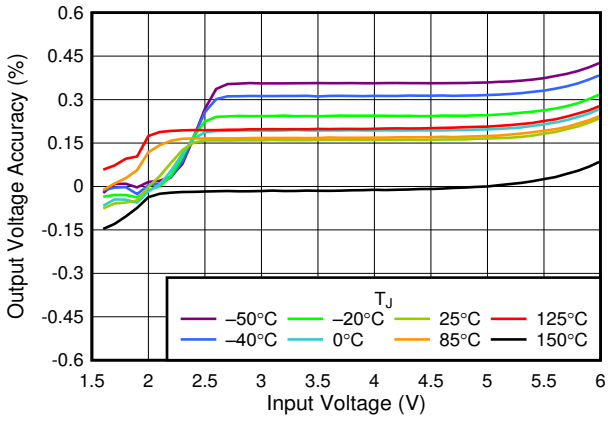

$V_{OUT}$ = 3.3 V, $I_{OUT}$ = 1 mA

**Figure 6-6. 3.3-V Line Regulation vs $V_{IN}$**

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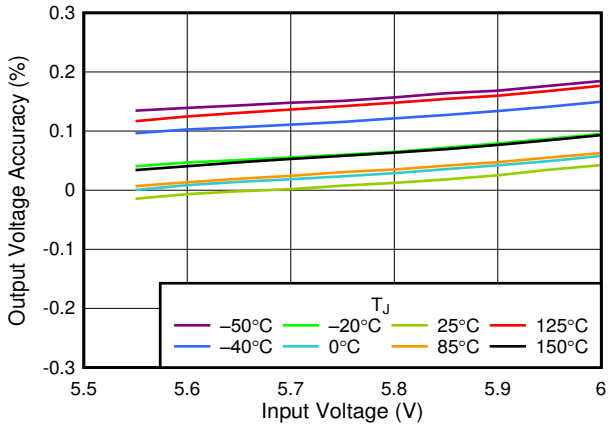
## 6.7 Typical Characteristics (continued)

at operating temperature range $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $V_{EN}$ = $V_{IN}$, and $C_{IN}$ = $C_{OUT}$ = 1 µF (unless otherwise noted)




$V_{OUT}$ = 0.55 V, $I_{OUT}$ = 1 mA

**Figure 6-7. 0.55-V Line Regulation vs $V_{IN}$**




$V_{OUT}$ = 5.5 V, $I_{OUT}$ = 1 mA

**Figure 6-8. 5.5-V Line Regulation vs $V_{IN}$**

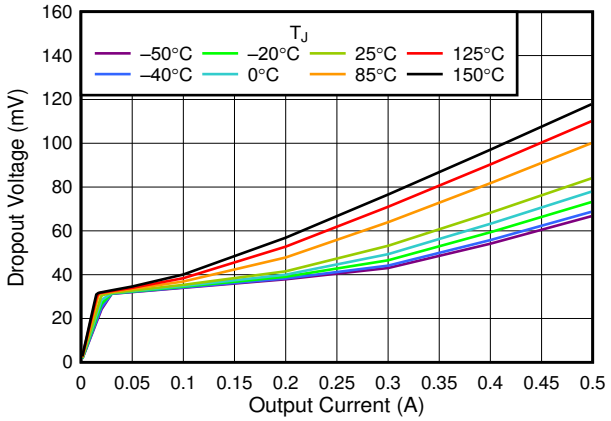



**Figure 6-9. 3.3-V Dropout Voltage vs $I_{OUT}$**

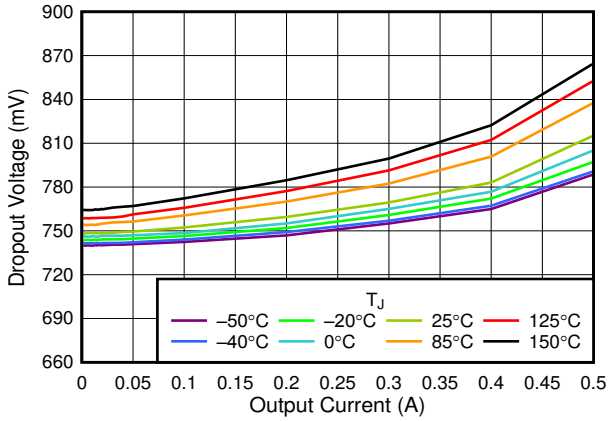



**Figure 6-10. 0.55-V Dropout Voltage vs $I_{OUT}$**

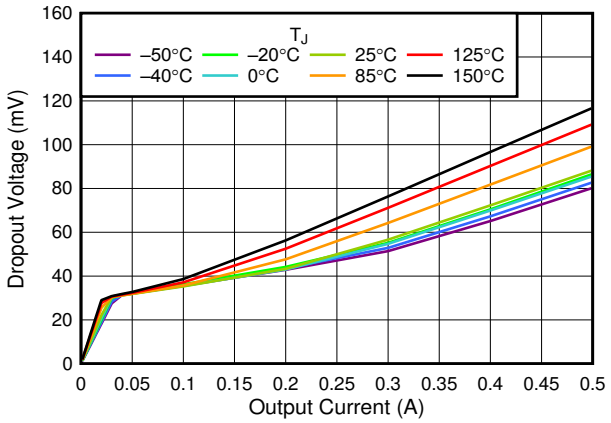
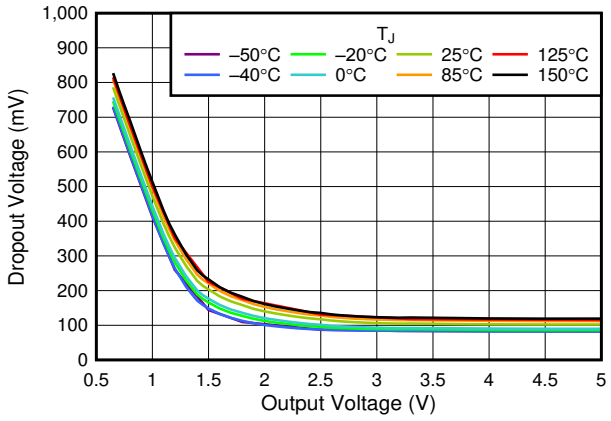



**Figure 6-11. 5.5-V Dropout Voltage vs $I_{OUT}$**




$I_{OUT}$ = 500 mA

**Figure 6-12. $V_{DO}$ vs $V_{OUT}$**


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## 6.7 Typical Characteristics (continued)

at operating temperature range $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $V_{EN}$ = $V_{IN}$, and $C_{IN}$ = $C_{OUT}$ = 1 µF (unless otherwise noted)

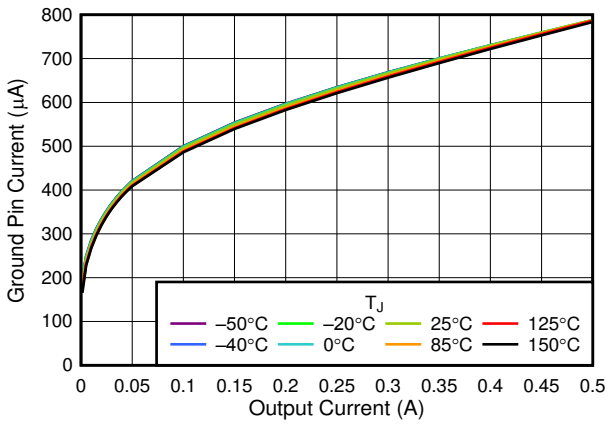
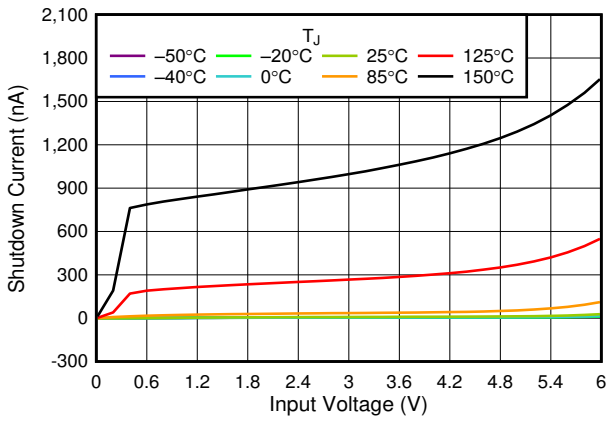
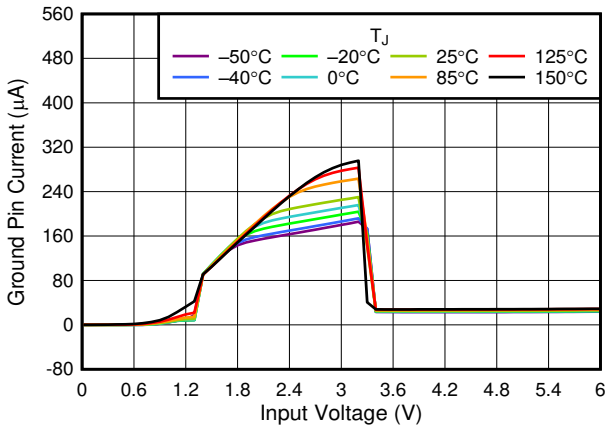



**Figure 6-13. $I_{GND}$ vs $I_{OUT}$**



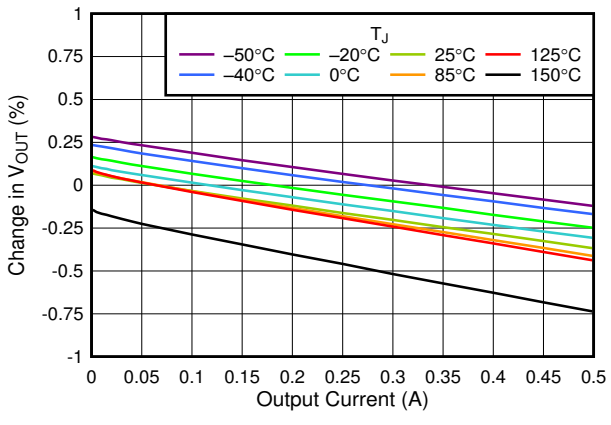

$V_{EN}$ = 0 V

**Figure 6-14. $I_{SHDN}$ vs $V_{IN}$**



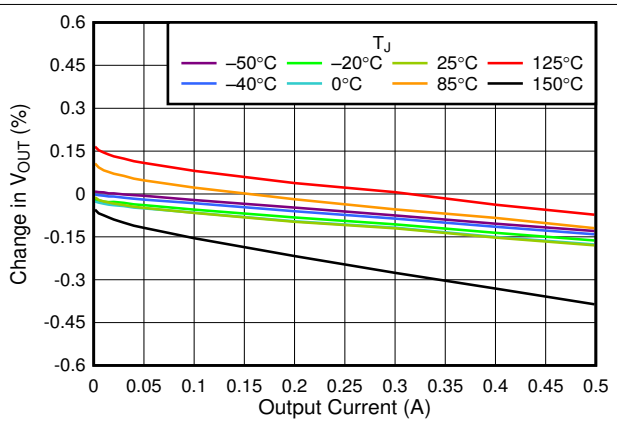

$V_{OUT}$ = 3.3 V, $I_{OUT}$ = 0 mA

**Figure 6-15. $I_Q$ vs $V_{IN}$**



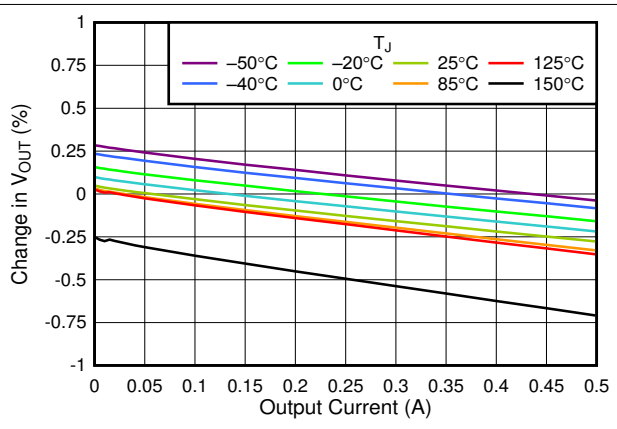

$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V

**Figure 6-16. 3.3-V Load Regulation vs $I_{OUT}$**




$V_{IN}$ = 2 V, $V_{OUT}$ = 0.55 V

**Figure 6-17. 0.55-V Load Regulation vs $I_{OUT}$**




$V_{IN}$ = 6 V, $V_{OUT}$ = 5.5 V

**Figure 6-18. 5.5-V Load Regulation vs $I_{OUT}$**

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## 6.7 Typical Characteristics (continued)

at operating temperature range $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $V_{EN}$ = $V_{IN}$, and $C_{IN}$ = $C_{OUT}$ = 1 µF (unless otherwise noted)

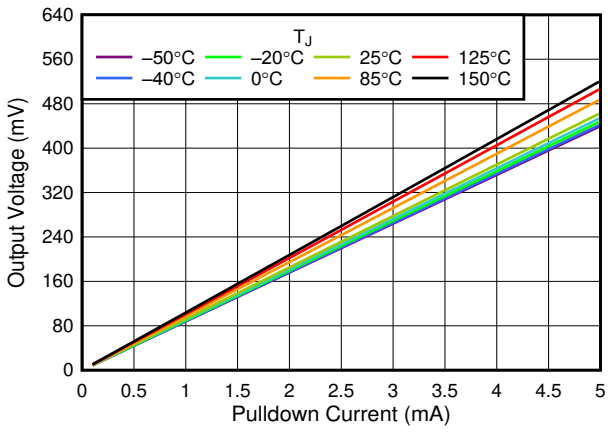



**Figure 6-19. $V_{OUT}$ vs $I_{OUT}$ Pulldown Resistor**

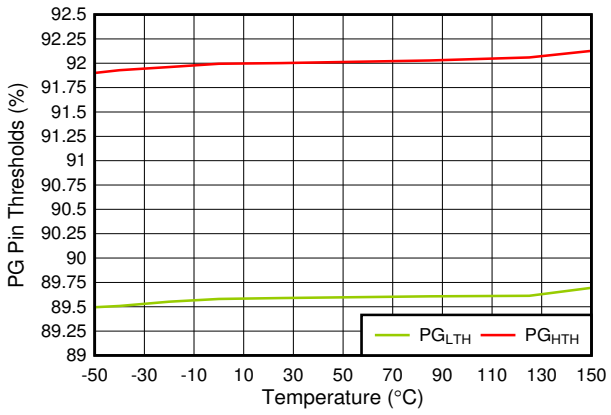



**Figure 6-20. $PG_{LTH}$ and $PG_{HTH}$ vs Temperature**

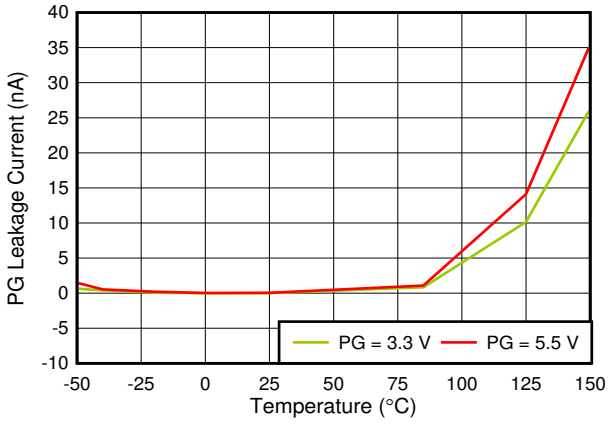
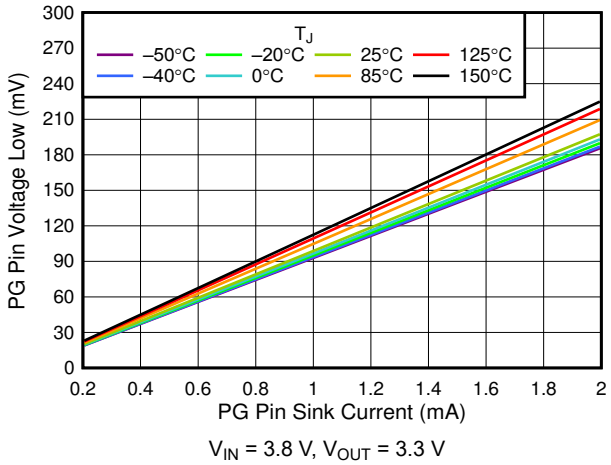
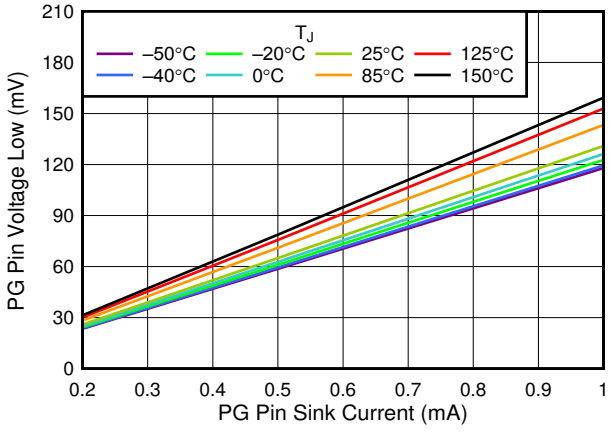



**Figure 6-21. $I_{lkg(PG)}$ vs Temperature and PG Pin Voltage**




$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V

**Figure 6-22. $V_{OL(PG)}$ vs PG Pin Sink Current**




$V_{IN}$ = 1.5 V, $V_{OUT}$ = 0.55 V

**Figure 6-23. $V_{OL(PG)}$ vs PG Pin Sink Current**

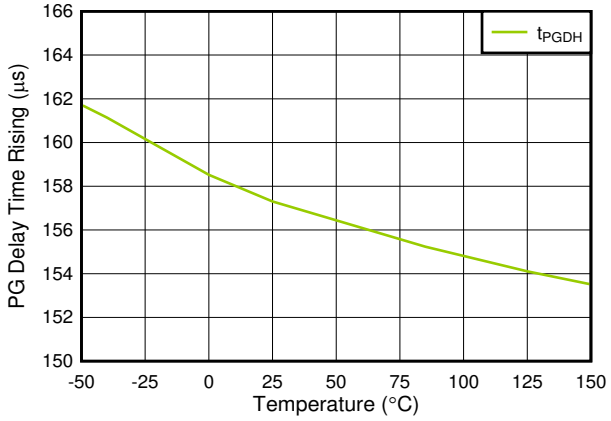



**Figure 6-24. $t_{PGDH}$ vs Temperature**


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## 6.7 Typical Characteristics (continued)

at operating temperature range $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $V_{EN}$ = $V_{IN}$, and $C_{IN}$ = $C_{OUT}$ = 1 µF (unless otherwise noted)

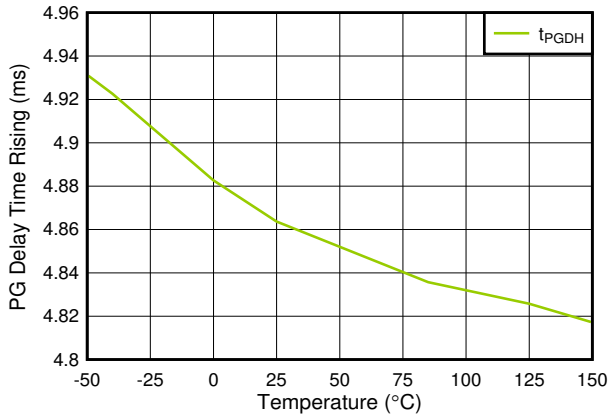



**Figure 6-25. $t_{PGDH}$ vs Temperature (For TPS746B Only)**

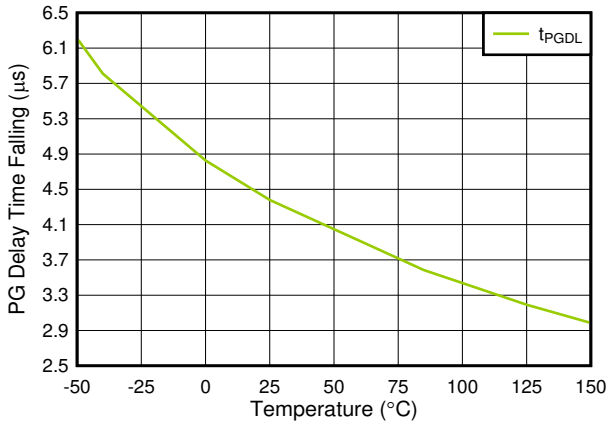



**Figure 6-26. $t_{PGDL}$ vs Temperature**

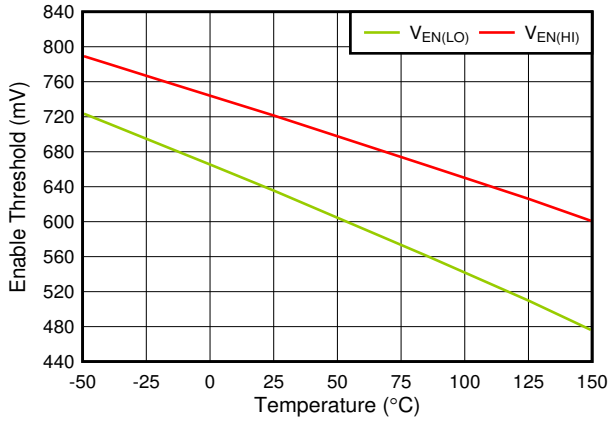



**Figure 6-27. $V_{EN(HI)}$ and $V_{EN(LO)}$ vs Temperature**

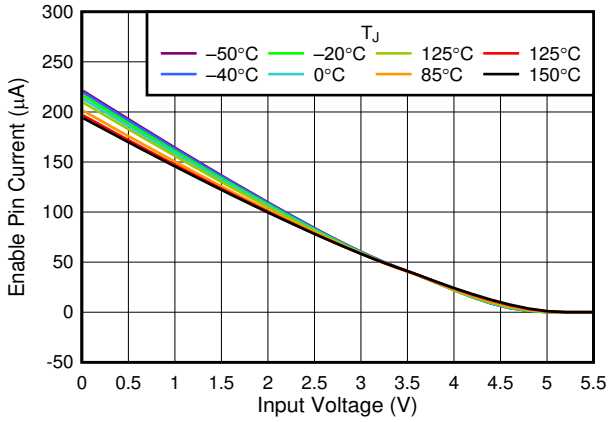



**Figure 6-28. $I_{EN}$ vs $V_{IN}$**

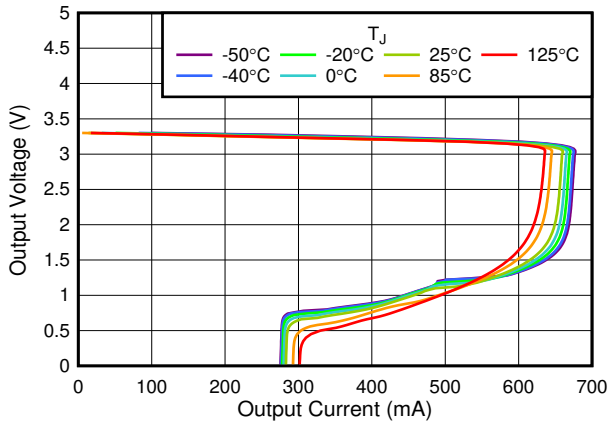
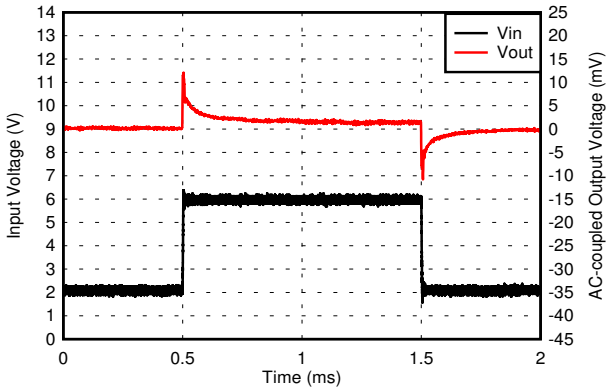



**Figure 6-29. 3.3-V $V_{OUT}$ vs $I_{OUT}$**



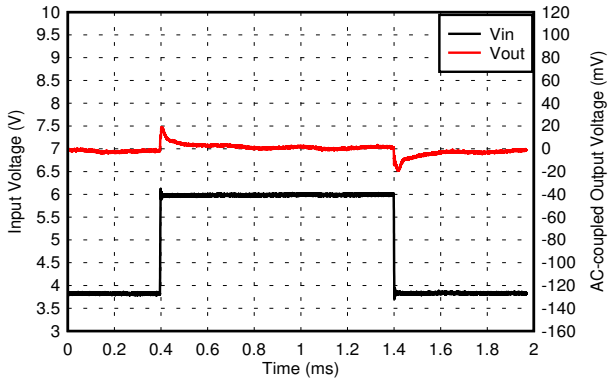

$V_{OUT}$ = 0.55 V, $I_{OUT}$ = 1 mA, $V_{IN}$ slew rate = 1 V/µs

**Figure 6-30. 0.55-V Line Transient**

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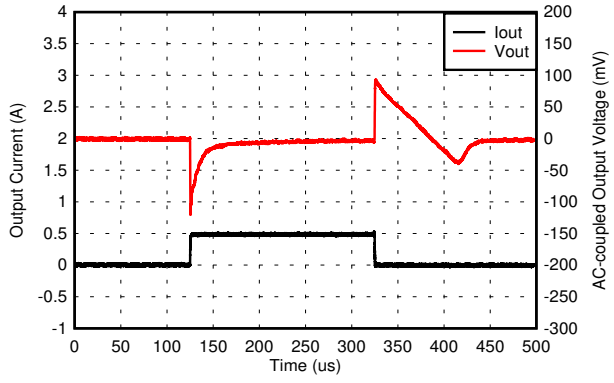
## 6.7 Typical Characteristics (continued)

at operating temperature range $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $V_{EN}$ = $V_{IN}$, and $C_{IN}$ = $C_{OUT}$ = 1 µF (unless otherwise noted)



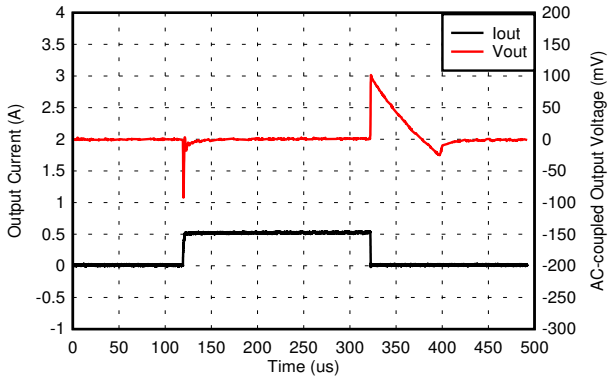

$V_{OUT}$ = 3.3 V, $I_{OUT}$ = 1 mA, $V_{IN}$ slew rate = 1 V/µs

**Figure 6-31. 3.3-V Line Transient**



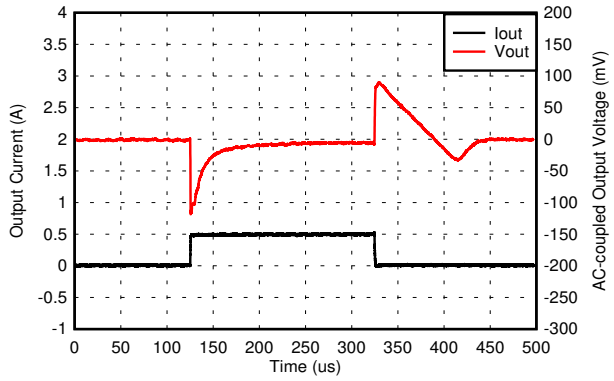

$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V, $I_{OUT}$ slew rate = 1 A/µs

**Figure 6-32. 3.3-V, 1-mA to 500-mA Load Transient**



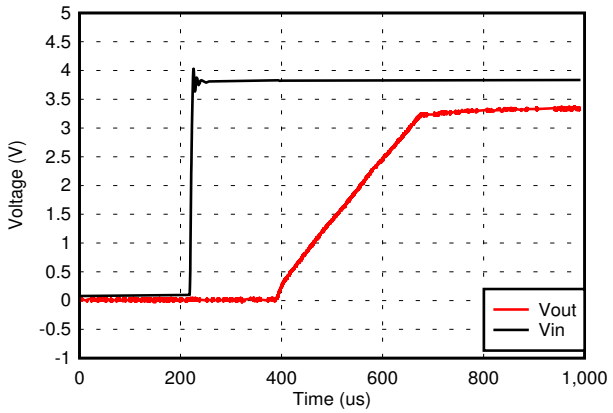

$V_{IN}$ = 2 V, $V_{OUT}$ = 0.55 V, $I_{OUT}$ slew rate = 1 A/µs

**Figure 6-33. 0.55-V, 1-mA to 500-mA Load Transient**



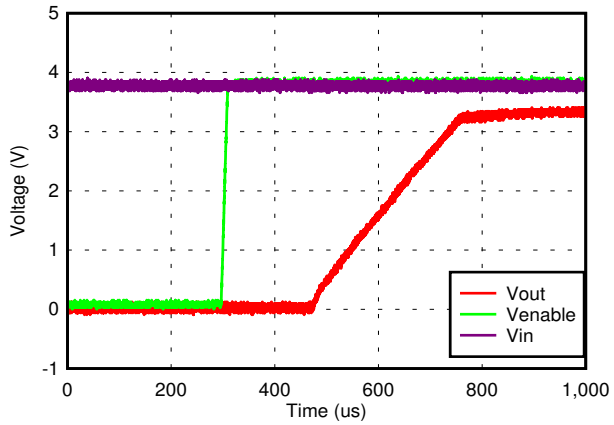

$V_{IN}$ = 5.5 V, $V_{OUT}$ = 5 V, $I_{OUT}$ slew rate = 1 A/µs

**Figure 6-34. 5-V, 1-mA to 500-mA Load Transient**




$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V, $I_{OUT}$ = 1 mA

**Figure 6-35. $V_{IN}$ Power-Up**



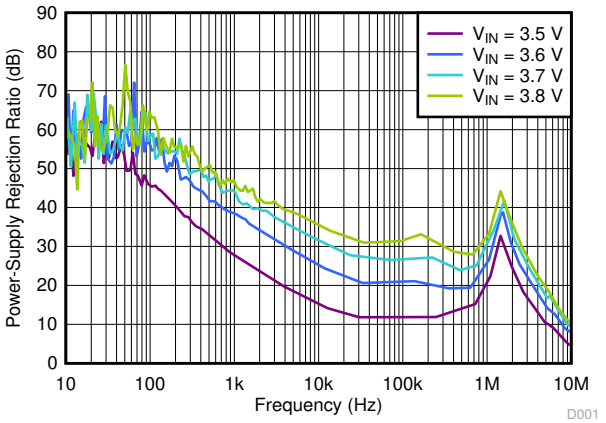

$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V, $I_{OUT}$ = 1 mA

**Figure 6-36. Start-Up With EN**


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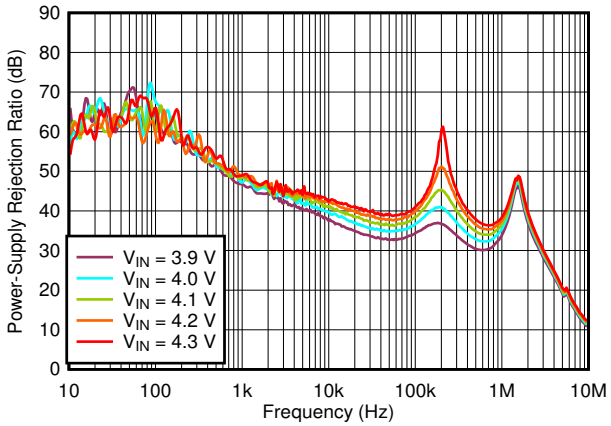
## 6.7 Typical Characteristics (continued)

at operating temperature range $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $V_{EN}$ = $V_{IN}$, and $C_{IN}$ = $C_{OUT}$ = 1 µF (unless otherwise noted)



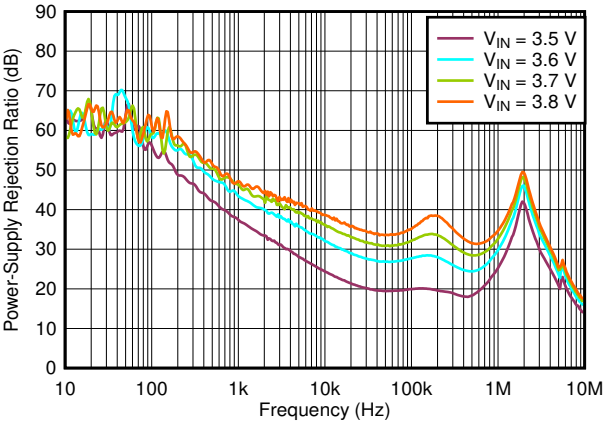

$V_{OUT}$ = 3.3 V, $I_{OUT}$ = 500 mA, $C_{OUT}$ = 2.2 µF

**Figure 6-37. PSRR vs Frequency and $V_{IN}$**



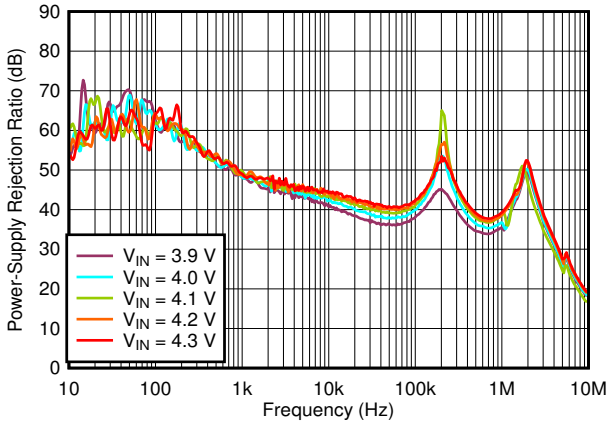

$V_{OUT}$ = 3.3 V, $I_{OUT}$ = 500 mA, $C_{OUT}$ = 2.2 µF

**Figure 6-38. PSRR vs Frequency and $V_{IN}$**



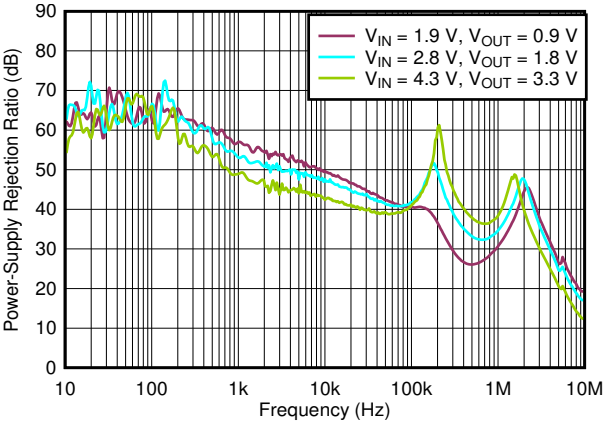

$V_{OUT}$ = 3.3 V, $I_{OUT}$ = 250 mA, $C_{OUT}$ = 2.2 µF

**Figure 6-39. PSRR vs Frequency and $V_{IN}$**



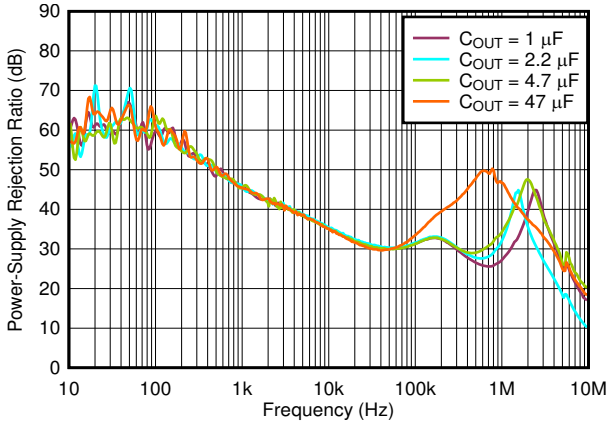

$V_{OUT}$ = 3.3 V, $I_{OUT}$ = 250 mA, $C_{OUT}$ = 2.2 µF

**Figure 6-40. PSRR vs Frequency and $V_{IN}$**




$I_{OUT}$ = 500 mA, $C_{OUT}$ = 2.2 µF

**Figure 6-41. PSRR vs Frequency**



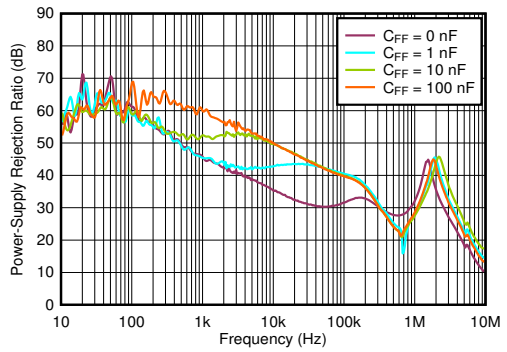

$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V, $I_{OUT}$ = 500 mA

**Figure 6-42. PSRR vs Frequency and $C_{OUT}$**

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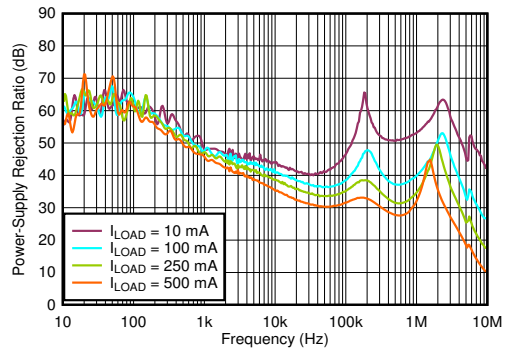
## 6.7 Typical Characteristics (continued)

at operating temperature range $T_J$ = 25°C, $V_{IN}$ = $V_{OUT(NOM)}$ + 0.5 V or 1.5 V (whichever is greater), $I_{OUT}$ = 1 mA, $V_{EN}$ = $V_{IN}$, and $C_{IN}$ = $C_{OUT}$ = 1 µF (unless otherwise noted)



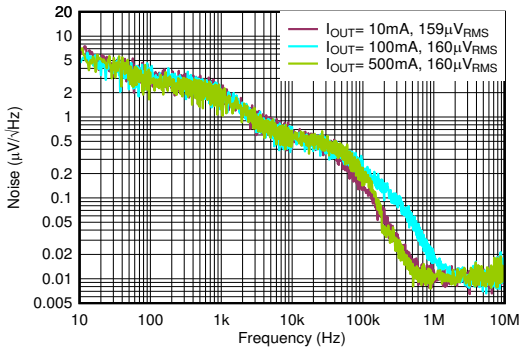

$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V, $I_{OUT}$ = 500 mA

**Figure 6-43. PSRR vs Frequency and $C_{FF}$**



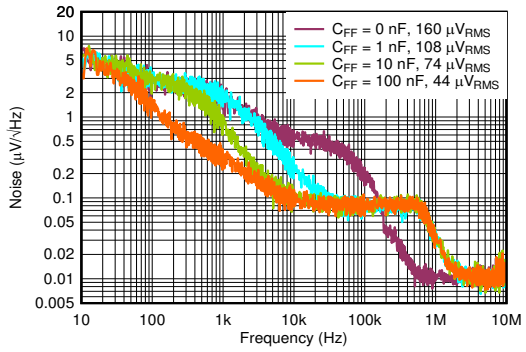

$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V, $C_{OUT}$ = 2.2 µF

**Figure 6-44. PSRR vs Frequency and $I_{LOAD}$**



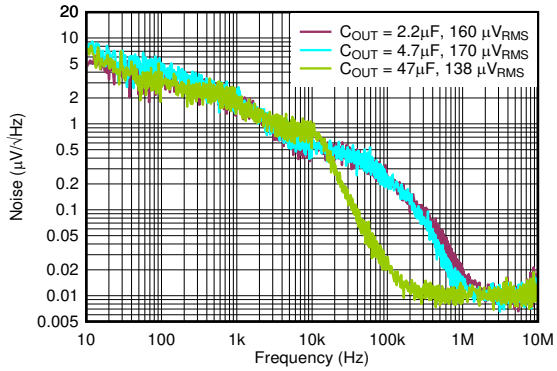

$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V, $C_{OUT}$ = 2.2 µF, $V_{RMS}$ BW = 10 Hz to 100 kHz

**Figure 6-45. Output Spectral Noise Density vs Frequency and $I_{OUT}$**



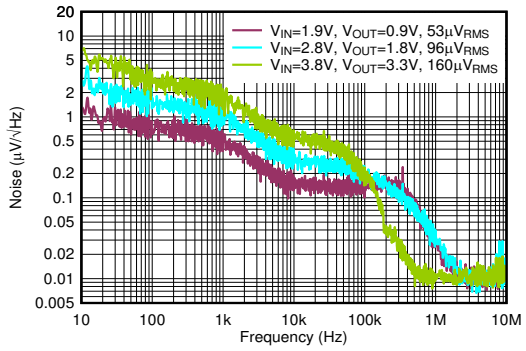

$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V, $I_{OUT}$ = 500 mA, $C_{OUT}$ = 2.2 µF, $V_{RMS}$ BW = 10 Hz to 100 kHz

**Figure 6-46. Output Spectral Noise Density vs Frequency and $C_{FF}$**




$V_{IN}$ = 3.8 V, $V_{OUT}$ = 3.3 V, $I_{OUT}$ = 100 mA, $C_{FF}$ = 0 µF, $V_{RMS}$ BW = 10 Hz to 100 kHz

**Figure 6-47. Output Spectral Noise Density vs Frequency and $C_{OUT}$**




$I_{OUT}$ = 500 mA, $C_{OUT}$ = 2.2 µF, $V_{RMS}$ BW = 10 Hz to 100 kHz

**Figure 6-48. Output Spectral Noise Density vs Frequency**


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# 7 Detailed Description

## 7.1 Overview

The TPS745-Q1 is a low-dropout regulator (LDO) that consumes low quiescent current and delivers excellent line and load transient performance. These characteristics, combined with low noise, good PSRR with low dropout voltage, make this device ideal for automotive applications.

This regulator offers foldback current limit, shutdown, and thermal protection. The operating junction temperature for this device is –40°C to +150°C.

## 7.2 Functional Block Diagrams

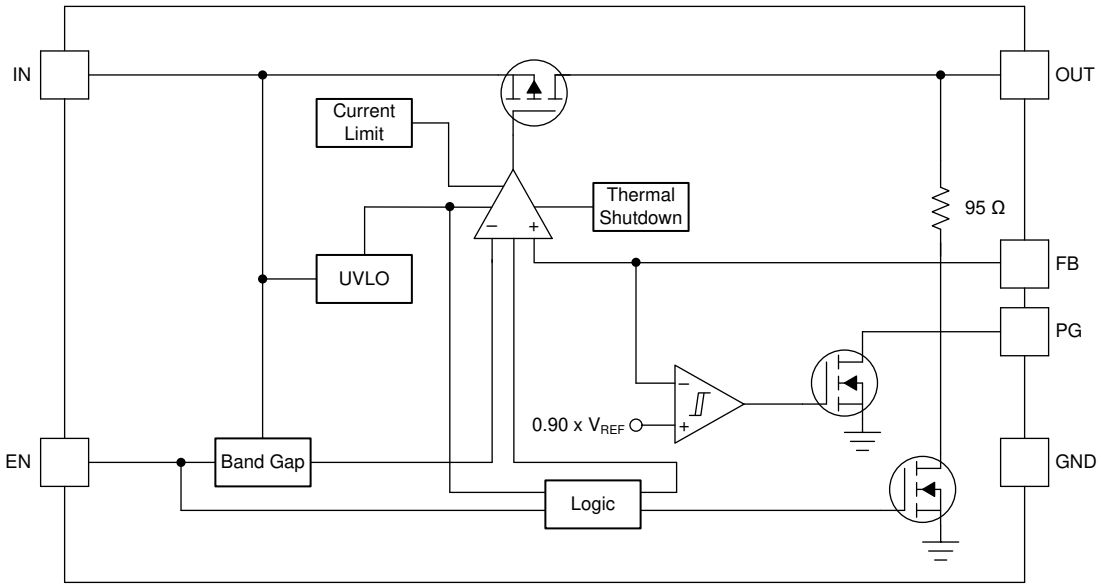



**Figure 7-1. Adjustable Version With Open-Drain Power-Good**

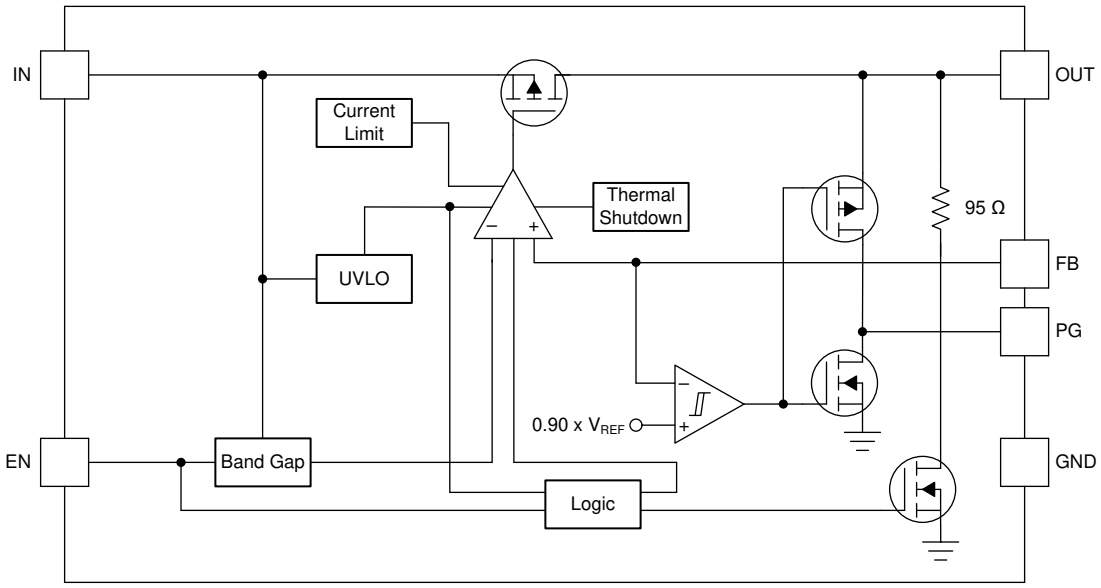



**Figure 7-2. Adjustable Version With Push-Pull Power-Good**

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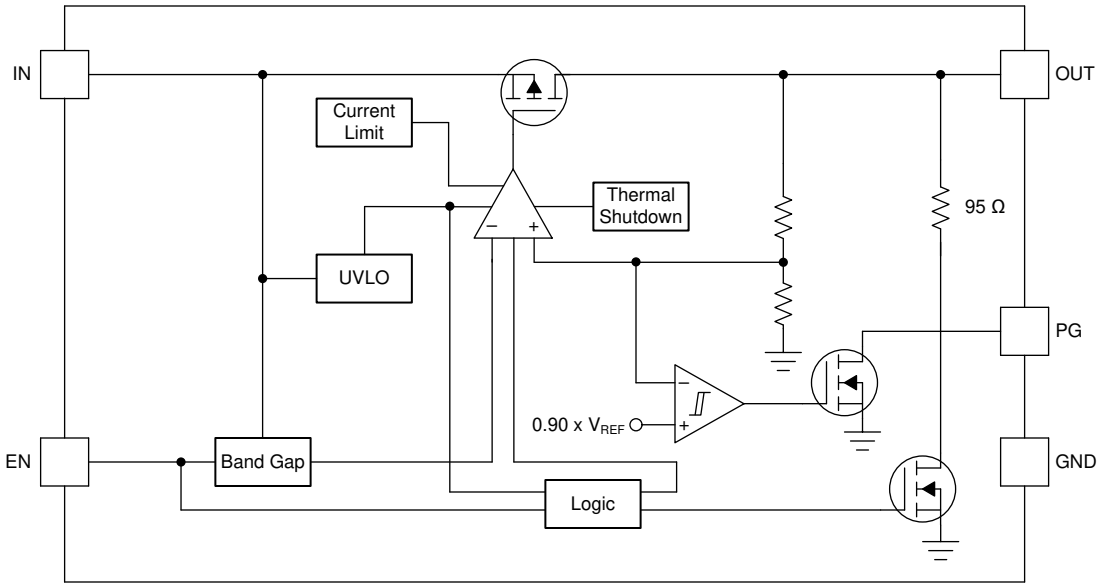



**Figure 7-3. Fixed Voltage Version With Open-Drain Power-Good**

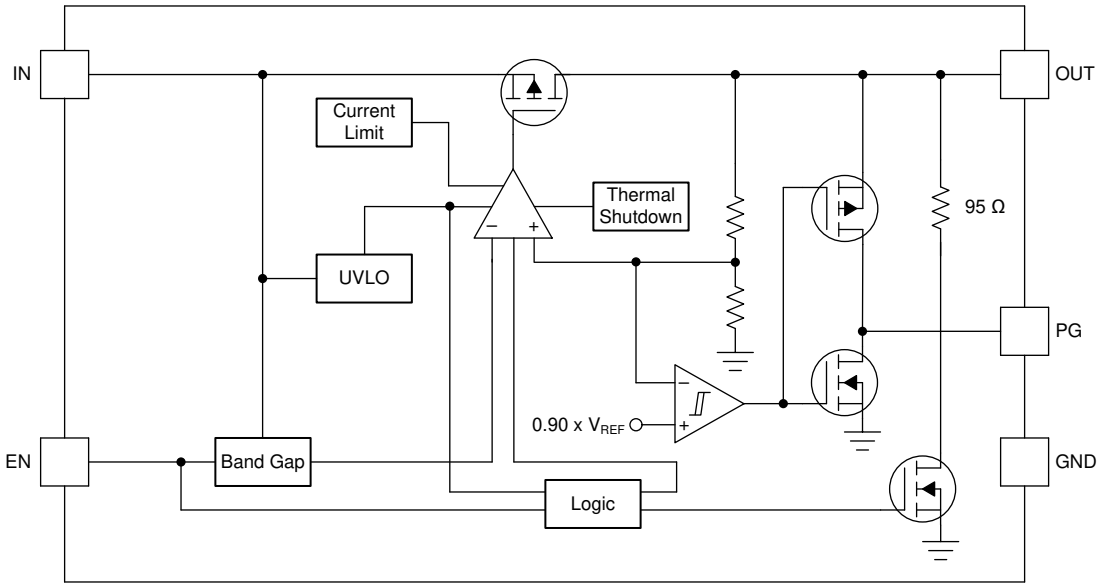



**Figure 7-4. Fixed Voltage Version With Push-Pull Power-Good**


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## 7.3 Feature Description

### 7.3.1 TPS745-Q1 Comparison

Table 7-1 lists the three different power-good (PG) options for the TPS745-Q1.

**Table 7-1. TPS745-Q1 Comparison Table**

| DEVICE | POWER-GOOD DELAY | POWER-GOOD TYPE |
|---|---|---|
| TPS745xxPQWDRVRQ1, TPS745xxPQWDRBRQ1 | 150 µs | Open-drain |
| TPS745xxPBQWDRVRQ1 | 5 ms | Open-drain |
| TPS745xxPCQWDRVRQ1 | 150 µs | Push-pull |

### 7.3.2 Undervoltage Lockout (UVLO)

The TPS745-Q1 uses an undervoltage lockout (UVLO) circuit that disables the output until the input voltage is greater than the rising UVLO voltage ($V_{UVLO}$). This circuit ensures that the device does not exhibit any unpredictable behavior when the supply voltage is lower than the operational range of the internal circuitry. When $V_{IN}$ is less than $V_{UVLO}$, the output is connected to ground with a pulldown resistor ($R_{PULLDOWN}$). When the device enters UVLO, the PG output is pulled low.

### 7.3.3 Shutdown

The enable pin (EN) is active high. Enable the device by forcing the EN pin to exceed $V_{EN(HI)}$. Turn off the device by forcing the EN pin to drop below $V_{EN(LO)}$. If shutdown capability is not required, connect EN to IN. When the device is disabled, the PG output pin is pulled low.

The TPS745-Q1 has an internal pulldown MOSFET that connects an $R_{PULLDOWN}$ resistor to ground when the device is disabled. The discharge time after disabling depends on the output capacitance ($C_{OUT}$) and the load resistance ($R_L$) in parallel with the pulldown resistor ($R_{PULLDOWN}$ ). Equation 1 calculates the time constant:

$$\tau = ( R_{PULLDOWN} \times R_L) / (R_{PULLDOWN} + R_L) \times C_{OUT} \quad (1)$$

### 7.3.4 Foldback Current Limit

The device has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events. The current limit is a hybrid brick-wall-foldback scheme. The current limit transitions from a brick-wall scheme to a foldback scheme at the foldback voltage ($V_{FOLDBACK}$). In a high-load current fault with the output voltage above $V_{FOLDBACK}$, the brick-wall scheme limits the output current to the current limit ($I_{CL}$). When the voltage drops below $V_{FOLDBACK}$, a foldback current limit activates that scales back the current as the output voltage approaches GND. When the output is shorted, the device supplies a typical current called the short-circuit current limit ($I_{SC}$). $I_{CL}$ and $I_{SC}$ are listed in the *Electrical Characteristics* table.

For this device, $V_{FOLDBACK} = 0.4 \times V_{OUT(NOM)}$.

The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in brickwall current limit, the pass transistor dissipates power [$(V_{IN} – V_{OUT}) \times I_{CL}$]. When the device output is shorted and the output is below $V_{FOLDBACK}$, the pass transistor dissipates power [$(V_{IN} – V_{OUT}) \times I_{SC}$]. If thermal shutdown is triggered, the device turns off. After the device cools down, the internal thermal shutdown circuit turns the device back on. If the output current fault condition continues, the device cycles between current limit and thermal shutdown. For more information on current limits, see the *Know Your Limits* application report.

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Figure 7-5 shows a diagram of the foldback current limit.

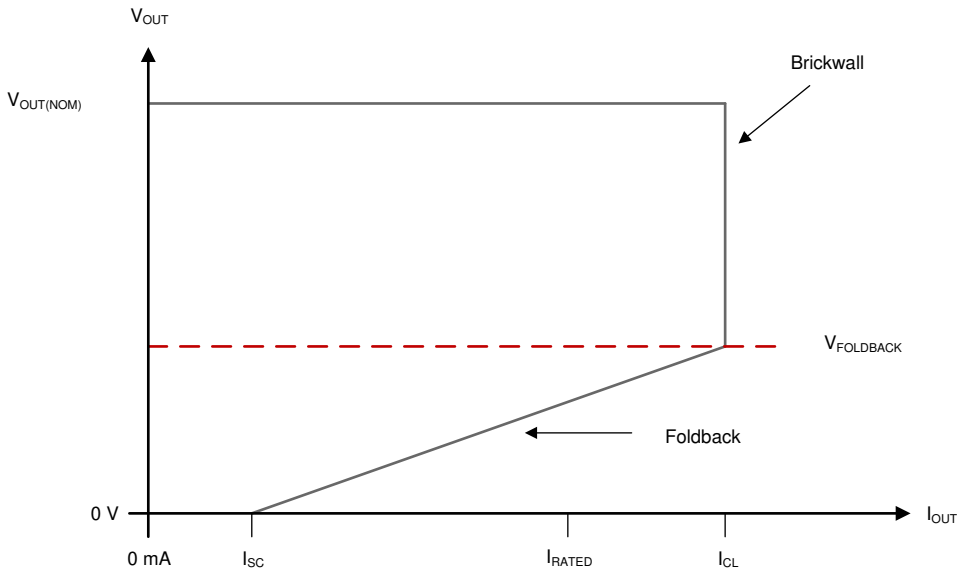



**Figure 7-5. Foldback Current Limit**

### 7.3.5 Thermal Shutdown

Thermal shutdown protection disables the output when the junction temperature rises to approximately 170°C. Disabling the device eliminates the power dissipated by the device, allowing the device to cool. When the junction temperature cools to approximately 155°C, the output circuitry is again enabled. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits regulator dissipation, protecting the regulator from damage as a result of overheating.

Activating the thermal shutdown feature usually indicates excessive power dissipation as a result of the product of the ($V_{IN}$ – $V_{OUT}$) voltage and the load current. For reliable operation, limit junction temperature to 150°C maximum. To estimate the margin of safety in a complete design, increase the ambient temperature until the thermal protection is triggered; use worst-case loads and signal conditions.

The TPS745-Q1 internal protection circuitry protects against overload conditions but is not intended to be activated in normal operation. Continuously running the TPS745-Q1 into thermal shutdown degrades device reliability.


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## 7.4 Device Functional Modes

### 7.4.1 Device Functional Mode Comparison

The *Device Functional Mode Comparison* table shows the conditions that lead to the different modes of operation. See the *Electrical Characteristics* table for parameter values.

**Table 7-2. Device Functional Mode Comparison**

| OPERATING MODE | PARAMETER | | | |
|---|---|---|---|---|
| | $V_{IN}$ | $V_{EN}$ | $I_{OUT}$ | $T_J$ |
| Normal operation | $V_{IN} > V_{OUT(nom)} + V_{DO}$ and $V_{IN} > V_{IN(min)}$ | $V_{EN} > V_{EN(HI)}$ | $I_{OUT} < I_{OUT(max)}$ | $T_J < T_{SD(shutdown)}$ |
| Dropout operation | $V_{IN(min)} < V_{IN} < V_{OUT(nom)} + V_{DO}$ | $V_{EN} > V_{EN(HI)}$ | $I_{OUT} < I_{OUT(max)}$ | $T_J < T_{SD(shutdown)}$ |
| Disabled (any true condition disables the device) | $V_{IN} < V_{UVLO}$ | $V_{EN} < V_{EN(LOW)}$ | Not applicable | $T_J > T_{SD(shutdown)}$ |

### 7.4.2 Normal Operation

The device regulates to the nominal output voltage when the following conditions are met:

- The input voltage is greater than the nominal output voltage plus the dropout voltage ($V_{OUT(nom)} + V_{DO}$)
- The output current is less than the current limit ($I_{OUT} < I_{CL}$)
- The device junction temperature is less than the thermal shutdown temperature ($T_J < T_{SD}$)
- The enable voltage has previously exceeded the enable rising threshold voltage and has not yet decreased to less than the enable falling threshold

### 7.4.3 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. During this mode, the transient performance of the device becomes significantly degraded because the pass transistor is in the ohmic or triode region, and acts as a switch. Line or load transients in dropout can result in large output-voltage deviations.

When the device is in a steady dropout state (defined as when the device is in dropout, $V_{IN} < V_{OUT(NOM)} + V_{DO}$, directly after being in a normal regulation state, but *not* during startup), the pass transistor is driven into the ohmic or triode region. When the input voltage returns to a value greater than or equal to the nominal output voltage plus the dropout voltage ($V_{OUT(NOM)} + V_{DO}$), the output voltage can overshoot for a short period of time while the device pulls the pass transistor back into the linear region.

### 7.4.4 Disabled

The output of the device can be shutdown by forcing the voltage of the enable pin to less than the maximum EN pin low-level input voltage (see the *Electrical Characteristics* table). When disabled, the pass transistor is turned off, internal circuits are shutdown, and the output voltage is actively discharged to ground by an internal discharge circuit from the output to ground.

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# 8 Application and Implementation

**Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 8.1 Application Information

### 8.1.1 Adjustable Device Feedback Resistors

Figure 8-1 shows that the output voltage of the TPS745P-Q1 can be adjusted from 0.55 V to 5.5 V by using a resistor divider network.

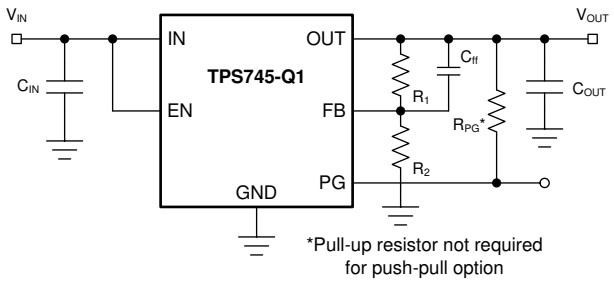



**Figure 8-1. Adjustable Operation**

The adjustable-version device requires external feedback divider resistors to set the output voltage. $V_{OUT}$ is set using the feedback divider resistors, $R_1$ and $R_2$, according to the following equation:

$$V_{OUT} = V_{FB} \times (1 + R_1 / R_2) \quad (2)$$

To ignore the FB pin current error term in the $V_{OUT}$ equation, set the feedback divider current to 100x the FB pin current listed in the *Electrical Characteristics* table. This setting provides the maximum feedback divider series resistance, as shown in the following equation:

$$R_1 + R_2 \leq V_{OUT} / (I_{FB} \times 100) \quad (3)$$

### 8.1.2 Input and Output Capacitor Selection

The TPS745-Q1 requires an output capacitance of 0.47 µF or larger for stability. Use X5R- and X7R-type ceramic capacitors because these capacitors have minimal variation in value and equivalent series resistance (ESR) over temperature. When choosing a capacitor for a specific application be mindful of the DC bias characteristics for the capacitor. Higher output voltages cause a significant derating of the capacitor. For best performance, the maximum recommended output capacitance is 220 µF.

Although an input capacitor is not required for stability, good analog design practice is to connect a capacitor from IN to GND. Some input supplies have a high impedance, thus placing the input capacitor on the input supply helps reduce the input impedance. This capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. If the input supply has a high impedance over a large range of frequencies, several input capacitors can be used in parallel to lower the impedance over frequency. Use a higher-value capacitor if large, fast, rise-time load transients are anticipated, or if the device is located several inches from the input power source.


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### 8.1.3 Dropout Voltage

The TPS745-Q1 uses a PMOS pass transistor to achieve low dropout. When ($V_{IN}$ – $V_{OUT}$) is less than the dropout voltage ($V_{DO}$), the PMOS pass device is in the linear region of operation and the input-to-output resistance is the $R_{DS(ON)}$ of the PMOS pass element. $V_{DO}$ scales approximately with output current because the PMOS device behaves like a resistor in dropout mode. As with any linear regulator, PSRR and transient response degrade as ($V_{IN}$ – $V_{OUT}$) approaches dropout operation.

### 8.1.4 Exiting Dropout

Some applications have transients that place the LDO into dropout, such as slower ramps on $V_{IN}$ during start-up. As with other LDOs, the output can overshoot on recovery from these conditions. A ramping input supply causes an LDO to overshoot on start-up, as shown in Figure 8-2, when the slew rate and voltage levels are in the correct range. Use an enable signal to avoid this condition.

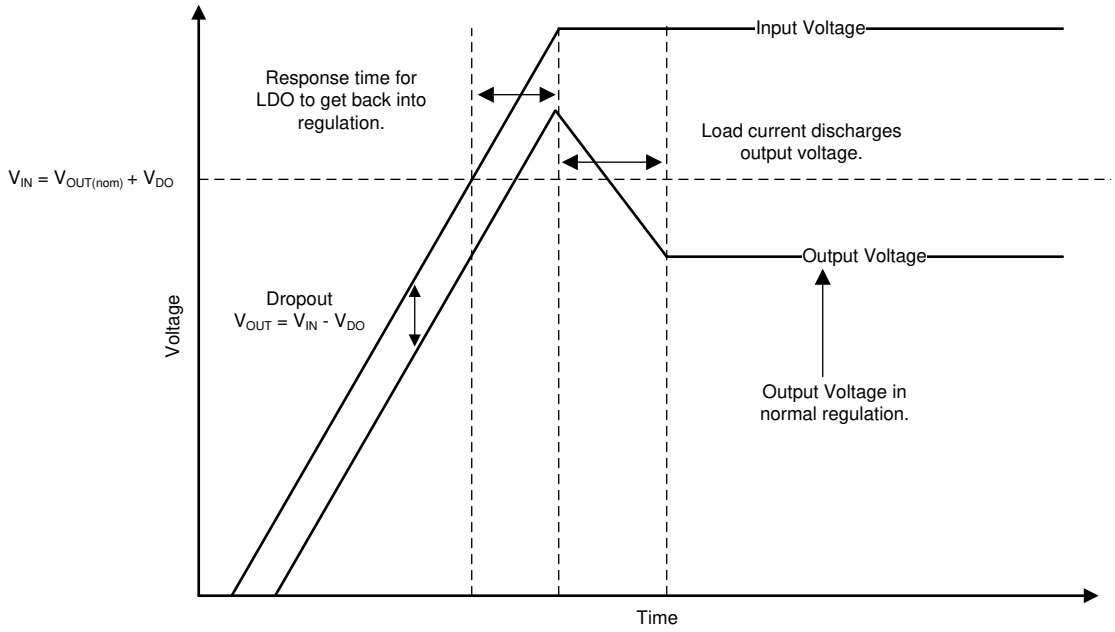



**Figure 8-2. Start-Up Into Dropout**

Line transients out of dropout can also cause overshoot on the output of the regulator. These overshoots are caused by the error amplifier having to drive the gate capacitance of the pass element and bring the gate back to the correct voltage for proper regulation. Figure 8-3 illustrates what is happening internally with the gate voltage and how overshoot can be caused during operation. When the LDO is placed in dropout, the gate voltage ($V_{GS}$) is pulled all the way down to ground to give the pass device the lowest on-resistance as possible. However, if a line transient occurs when the device is in dropout, the loop is not in regulation and can cause the output to overshoot until the loop responds and the output current pulls the output voltage back down into regulation. If these transients are not acceptable, then continue to add input capacitance in the system until the transient is slow enough to reduce the overshoot.

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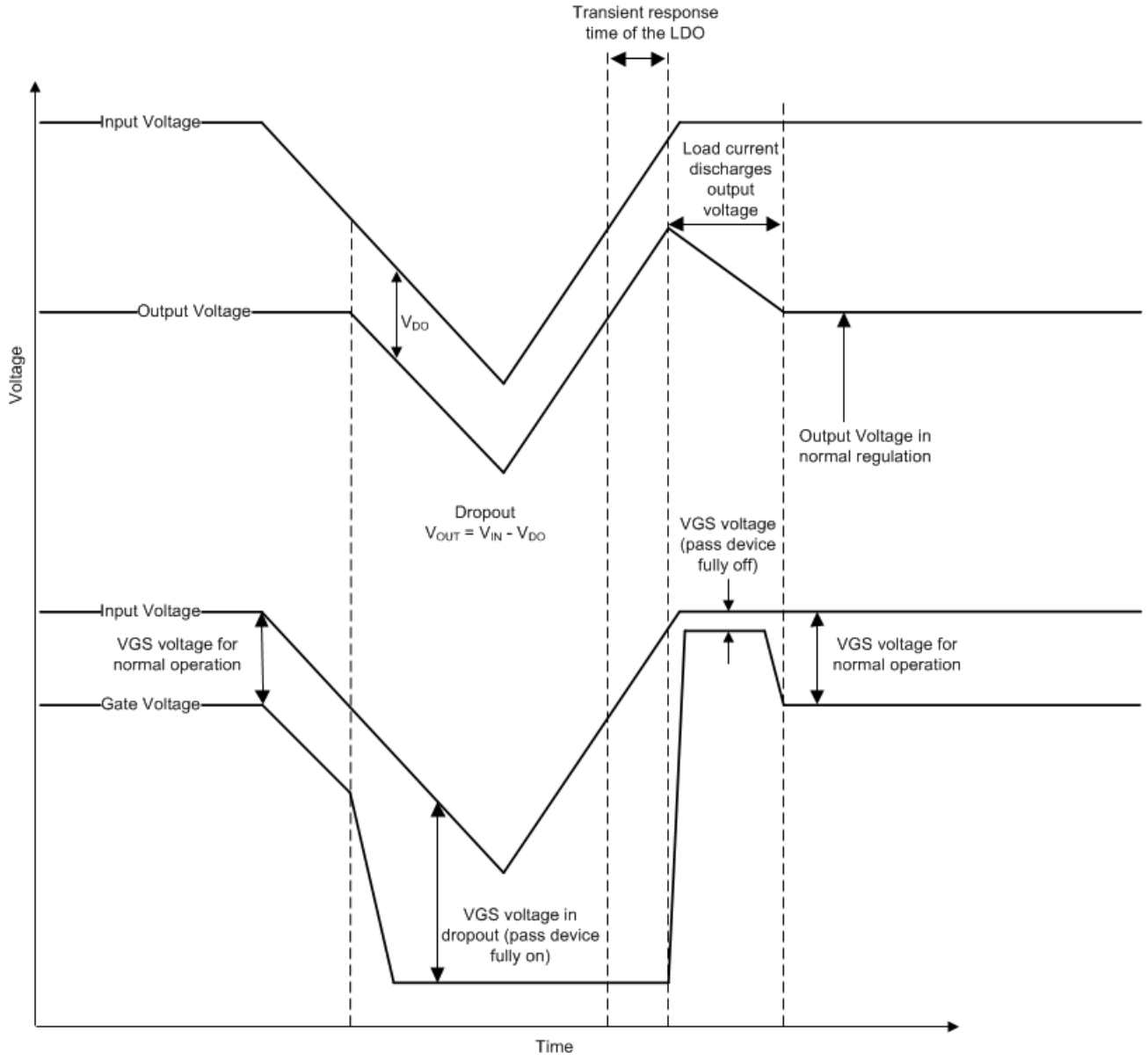



**Figure 8-3. Line Transients From Dropout**

### 8.1.5 Reverse Current

As with most LDOs, excessive reverse current can damage this device.

Reverse current flows through the body diode on the pass element instead of the normal conducting channel. At high magnitudes, this current flow degrades the long-term reliability of the device, as a result of one of the following conditions:

- Degradation caused by electromigration
- Excessive heat dissipation
- Potential for a latch-up condition

Conditions where reverse current can occur are outlined in this section, all of which can exceed the absolute maximum rating of $V_{OUT} > V_{IN} + 0.3$ V:

- If the device has a large $C_{OUT}$ and the input supply collapses with little or no load current
- The output is biased when the input supply is not established
- The output is biased above the input supply


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If reverse current flow is expected in the application, external protection must be used to protect the device. Figure 8-4 shows one approach of protecting the device.

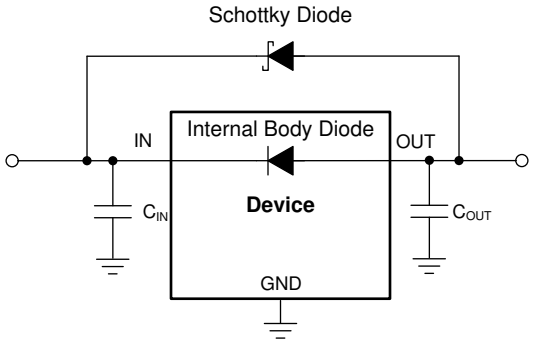



**Figure 8-4. Example Circuit for Reverse Current Protection Using a Schottky Diode**

### 8.1.6 Power Dissipation ($P_D$)

Circuit reliability requires consideration of the device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must have few or no other heat-generating devices that cause added thermal stress.

To first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. The following equation calculates power dissipation ($P_D$).

$$P_D = (V_{IN} – V_{OUT}) \times I_{OUT} \quad (4)$$

**Note**

Power dissipation can be minimized, and therefore greater efficiency can be achieved, by correct selection of the system voltage rails. For the lowest power dissipation use the minimum input voltage required for correct output regulation.

For devices with a thermal pad, the primary heat conduction path for the device package is through the thermal pad to the PCB. Solder the thermal pad to a copper pad area under the device. This pad area must contain an array of plated vias that conduct heat to additional copper planes for increased heat dissipation.

The maximum power dissipation determines the maximum allowable ambient temperature ($T_A$) for the device. According to the following equation, power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB and device package and the temperature of the ambient air ($T_A$).

$$T_J = T_A + (R_{\theta JA} \times P_D) \quad (5)$$

Thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The junction-to-ambient thermal resistance listed in the *Thermal Information* table is determined by the JEDEC standard PCB and copper-spreading area, and is used as a relative measure of package thermal performance.

Figure 8-5 and Figure 8-6 illustrate the functions of $R_{\theta JA}$ and $\psi_{JB}$ versus copper (Cu) area and thickness. These plots are generated with a 101.6-mm x 101.6-mm x 1.6-mm printed circuit board (PCB) of two and four layers. For the four-layer board, the inner planes use a 1-oz copper thickness. Outer layers are simulated with both 1-oz and 2-oz copper thickness. A 2 x 1 array of thermal vias of 300-µm drill diameter and 25-µm Cu plating is located beneath the thermal pad of the device. The thermal vias connect the top layer, the bottom layer and, in the case of the 4-layer board, the first inner GND plane.

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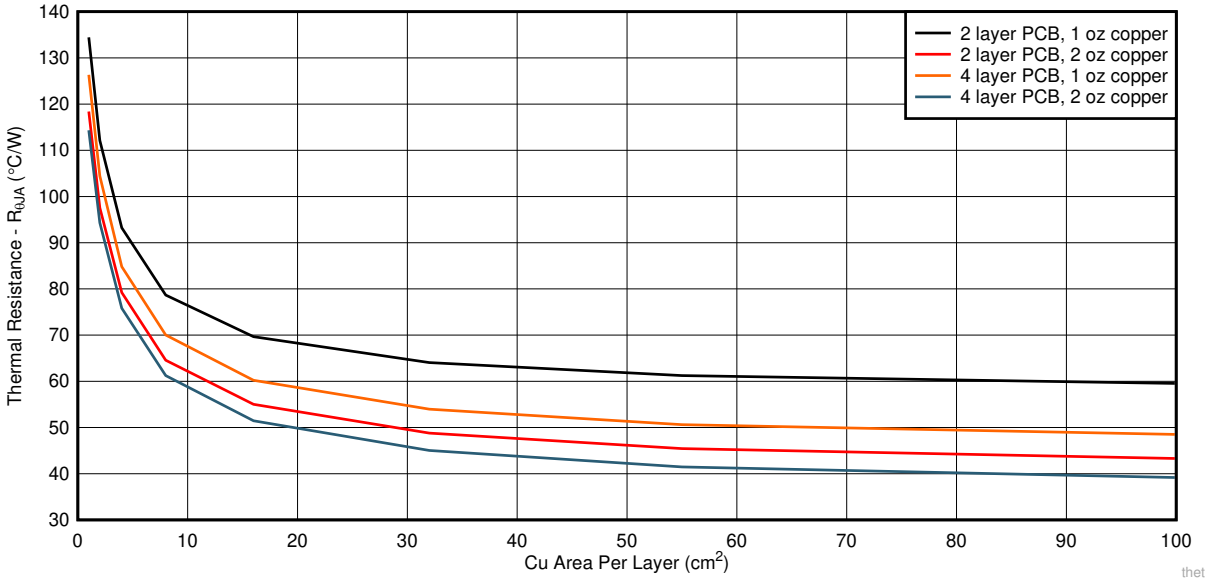



**Figure 8-5. $R_{\theta JA}$ versus Cu Area for the WSON (DRV) Package**

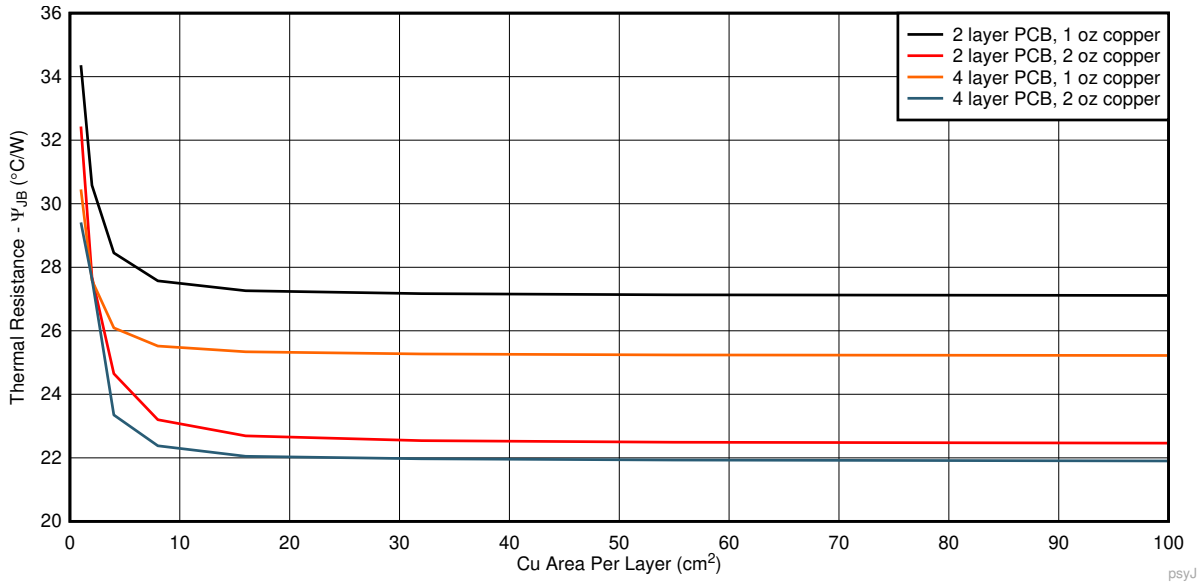
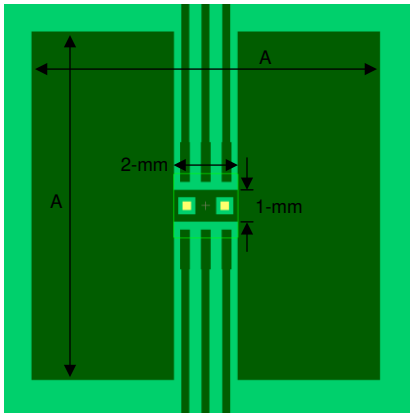



**Figure 8-6. $\psi_{JB}$ versus Cu Area for the WSON (DRV) Package**


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As shown in Figure 8-7, each layer has a copper plane of equal area.




Buried plane and bottom layer Cu ground planes are modeled with Area = A×A

**Figure 8-7. Board parameters used for simulation**

For a more comprehensive study of how thermal resistance varies with copper area and thickness, see the *An empirical analysis of the impact of board layout on LDO thermal performance* application report. As shown in Figure 8-8, modifying board layout to be more thermally enhanced can lower the $R_{\theta JA}$ value from 80.3°C/W to 46.8°C/W or better.

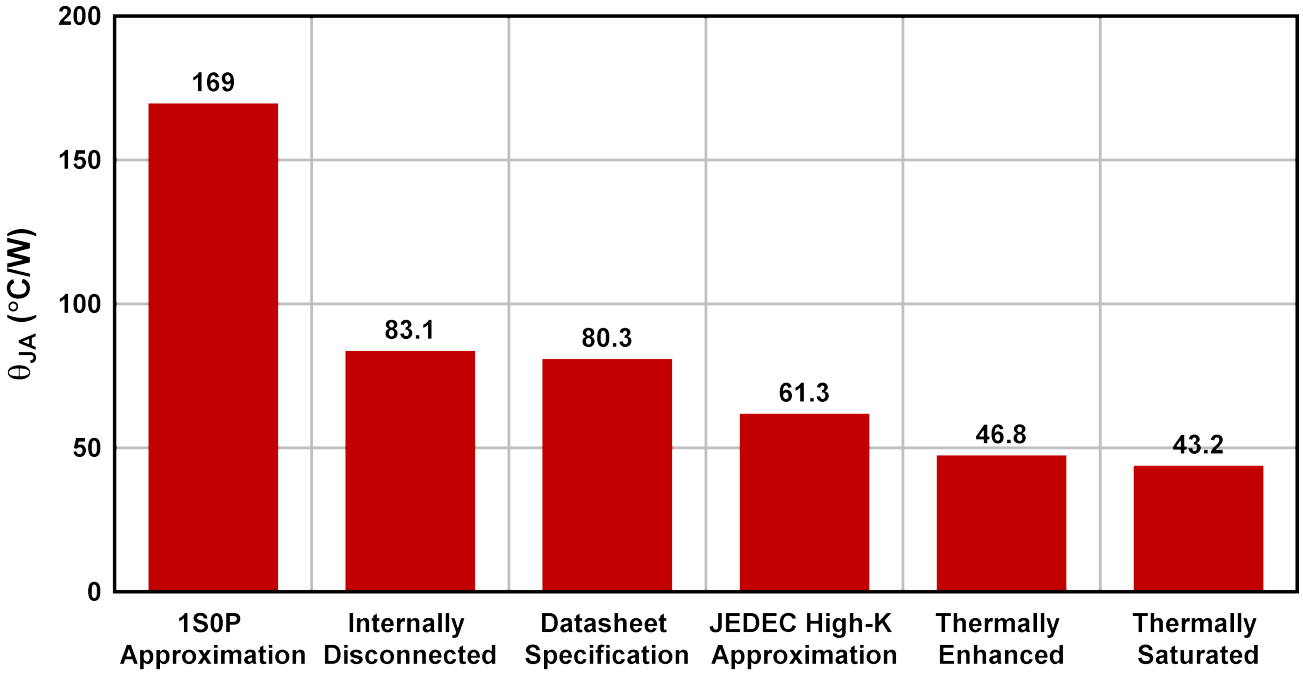



**Figure 8-8. TPS745-Q1 (WSON) $R_{\theta JA}$ versus Board Layout**

### 8.1.7 Power-Good Function

The power-good circuit monitors the voltage at the feedback pin to indicate the status of the output voltage. When the output voltage falls below the PG threshold voltage ($PG_{LTH}$), the PG pin open-drain output engages and pulls the PG pin close to GND. When the output voltage exceeds $PG_{HTH}$, the PG pin becomes high impedance. The open-drain output requires a pullup resistor. By connecting a pullup resistor to an external supply, any downstream device can receive power-good as a logic signal that can be used for sequencing. Additionally, the open-drain output can be tied to other open-drain outputs to implement AND logic. Make sure that the external pullup supply voltage results in a valid logic signal for the receiving device. Using a pullup resistor from 10 kΩ to 100 kΩ is recommended. The push-pull power-good option does not require the pullup resistor and instead has a high logic signal that correlates with the output voltage of the device. The push-pull option is supported only for $V_{OUT} \geq 1.0$ V. The push-pull option is supported only for $V_{OUT} \geq 1.0$ V. Do not tie the push-pull output to other logic outputs.

When using a feed-forward capacitor ($C_{FF}$), the time constant for the LDO start-up is increased whereas the power-good output time constant stays the same, possibly resulting in an invalid status of the power-good output. To avoid this issue, and to receive a valid PG output, make sure that the time constant of both the LDO start-up and the power-good output match, which can be done by adding a capacitor in parallel with the power-good pullup resistor. For more information, see the *Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator* application report.

The state of PG is only valid when the TPS745-Q1 operates above the minimum input voltage of the device and power-good is asserted, regardless of the output voltage state when the input voltage falls below the UVLO threshold minus the UVLO hysteresis. When the input voltage falls below approximately 0.8 V, there is not enough gate drive voltage to keep the open-drain, power-good device turned on and the power-good output pulled high. Connecting the power-good pullup resistor to the output voltage can help minimize this effect.

### 8.1.8 Feed-Forward Capacitor ($C_{FF}$)

For the adjustable-voltage version device, a feed-forward capacitor ($C_{FF}$) can be connected from the OUT pin to the FB pin. $C_{FF}$ improves transient, noise, and PSRR performance, but is not required for regulator stability. Recommended $C_{FF}$ values are listed in the *Recommended Operating Conditions* table. A higher capacitance $C_{FF}$ can be used; however, the startup time increases. For a detailed description of $C_{FF}$ tradeoffs, see the *Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator* application report.

### 8.1.9 Start-Up Sequencing

If $V_{EN}$ is greater than $V_{UVLO}$ rising (min), the input pin (IN) must sink 1 mA of current to avoid the device being turned on with a floating input pin.


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## 8.2 Typical Application

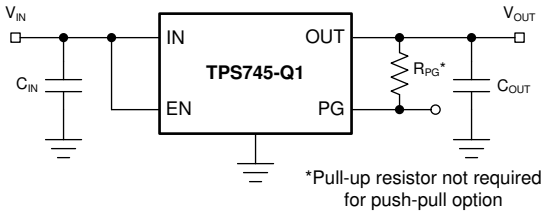



**Figure 8-9. TPS745-Q1 Typical Application**

### 8.2.1 Design Requirements

Table 8-1 summarizes the design requirements for Figure 8-9.

**Table 8-1. Design Parameters**

| PARAMETER | DESIGN REQUIREMENT |
|---|---|
| Input voltage | 3.3 V |
| Output voltage | 1.8 V, ±1% |
| Input current | 300 mA, maximum |
| Output load | 300-mA DC |
| Maximum ambient temperature | 105°C |

### 8.2.2 Detailed Design Procedure

Input and output capacitors are required to achieve the output voltage transient requirements. Capacitance values of 2.2 µF are selected to give the maximum output capacitance in a small, low-cost package; see the *Input and Output Capacitor Selection* section for details.

#### *8.2.2.1 Input Current*

During normal operation, the input current to the LDO is approximately equal to the output current of the LDO. During start-up, the input current is higher as a result of the inrush current charging the output capacitor. Use Equation 6 to calculate the current through the input.

$$I_{OUT(t)} = \left[\frac{C_{OUT} \times dV_{OUT}(t)}{dt}\right] + \left[\frac{V_{OUT}(t)}{R_{LOAD}}\right] \quad (6)$$

where:

- $V_{OUT}(t)$ is the instantaneous output voltage of the turn-on ramp
- $dV_{OUT}(t) / dt$ is the slope of the $V_{OUT}$ ramp
- $R_{LOAD}$ is the resistive load impedance

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#### 8.2.2.2 Thermal Dissipation

The junction temperature can be determined using the junction-to-ambient thermal resistance ($R_{\theta JA}$) and the total power dissipation ($P_D$). Use Equation 7 to calculate the power dissipation. Multiply $P_D$ by $R_{\theta JA}$ as Equation 8 shows and add the ambient temperature ($T_A$) to calculate the junction temperature ($T_J$).

$$P_D = (I_{GND} + I_{OUT}) \times (V_{IN} - V_{OUT}) \quad (7)$$

$$T_J = R_{\theta JA} \times P_D + T_A \quad (8)$$

Calculate the maximum ambient temperature according to Equation 9 and Equation 10. The maximum ambient temperature is 113.86°C for the example conditions.

$$T_{A(MAX)} = T_{J(MAX)} - R_{\theta JA} \times P_D \quad (9)$$

$$T_{A(MAX)} = 150°C - 80.3°C/W \times (3.3\ V - 1.8\ V) \times (0.3\ A) = 113.86°C \quad (10)$$

### 8.2.3 Application Curves

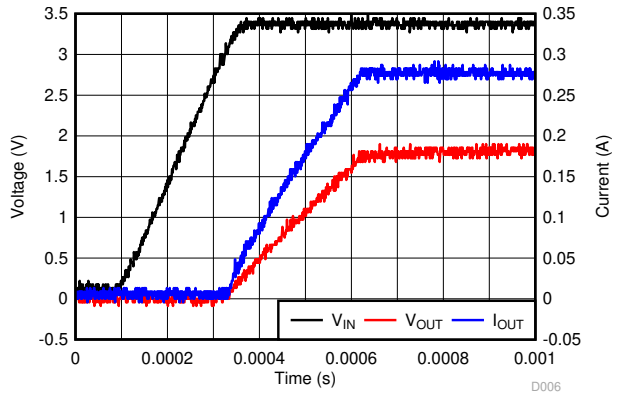



**Figure 8-10. Startup**

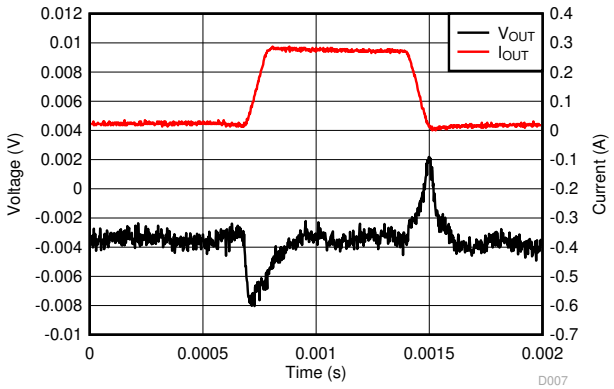



**Figure 8-11. Load Transient**

## 9 Power Supply Recommendations

The TPS745-Q1 is designed to operate from an input voltage supply range from 1.5 V to 6.0 V. The input voltage range provides adequate headroom for the device to have a regulated output. This input supply must be well regulated. If the input supply is noisy, additional input capacitors with low ESR can help improve output noise performance. Connect a low output impedance power supply directly to the IN pin of the TPS745-Q1.


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# 10 Layout

## 10.1 Layout Guidelines

- Place input and output capacitors as close to the device as possible.
- Use copper planes for device connections to optimize thermal performance.
- Place thermal vias around the device to distribute heat.
- Only place tented thermal vias directly beneath the thermal pad of the DRV or DRB package. An untented via can wick solder or solder paste away from the thermal pad joint during the soldering process, leading to a compromised solder joint on the thermal pad.

## 10.2 Layout Examples

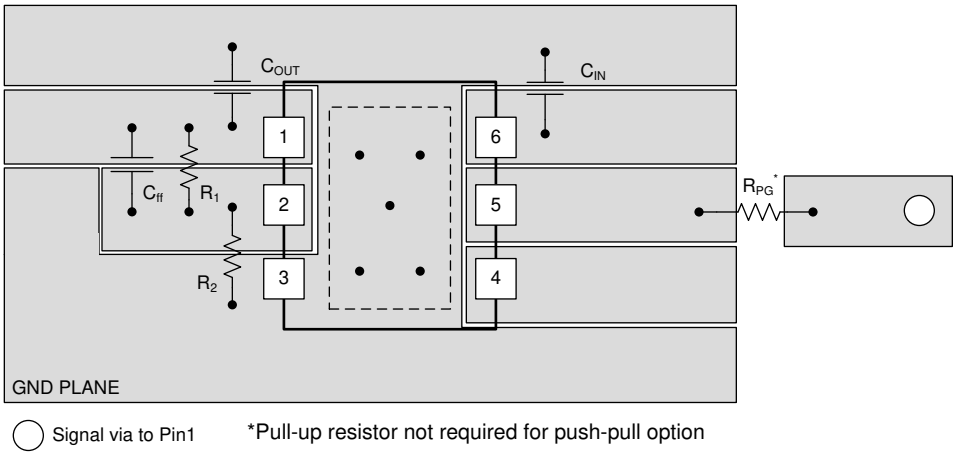



**Figure 10-1. Layout Example for the DRV Package**

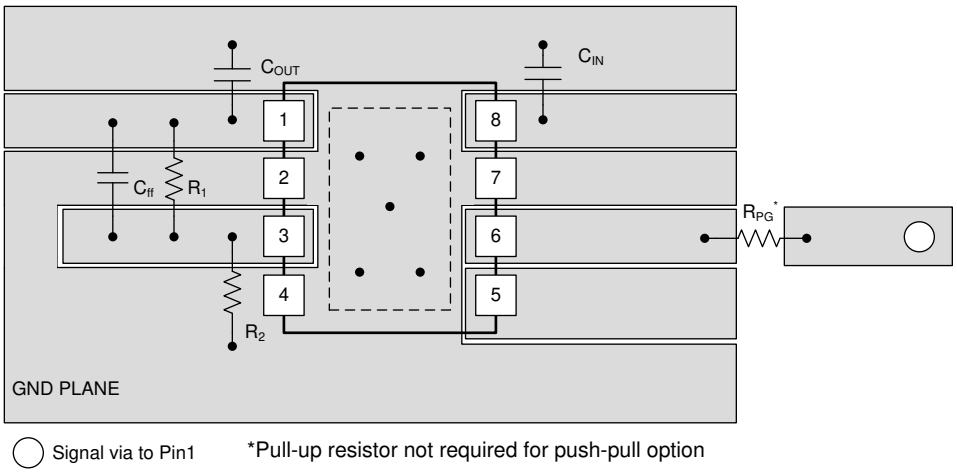



**Figure 10-2. Layout Example for the DRB Package**

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# 11 Device and Documentation Support

## 11.1 Device Support

### 11.1.1 Device Nomenclature

**Table 11-1. Device Nomenclature**(1) (2)

| PRODUCT | $V_{OUT}$ |
|---|---|
| TPS745**xx(x)PvQWyyyzQ1** | **xx(x)** is the nominal output voltage. For output voltages with a resolution of 100 mV, two digits are used in the ordering number; otherwise, three digits are used (for example, 28 = 2.8 V; 125 = 1.25 V; 01 = adjustable).<br>**P** indicates an active output discharge feature. All members of the TPS745-Q1 family actively discharge the output when the device is disabled.<br>**v** indicates the topology of the power-good output and the timing associated with the power-good delay.<br>• If unused, indicates an open-drain power-good output with a 150-µs delay.<br>• If **B**, indicates a open-drain power-good output with a 5-ms delay.<br>• If **C**, indicates a push-pull power-good output with a 150-µs delay.<br>**Q** indicates that this device is a Grade-1 device in accordance with the AEC-Q100 standard.<br>**W** indicates the package has wettable flanks.<br>**yyy** is the package designator.<br>**z** is the package quantity. R is for reel (3000 pieces), T is for tape (250 pieces).<br>**Q1** indicates that this device is an automotive grade (AEC-Q100) device. |

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder on www.ti.com.
(2) Output voltages from 0.65 V to 5.0 V in 50-mV increments are available. Contact the factory for details and availability.

## 11.2 Documentation Support

### 11.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, *An empirical analysis of the impact of board layout on LDO thermal performance* application report
- Texas Instruments, *Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator* application report

## 11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 11.4 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

## 11.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

## 11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.


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### 11.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

## Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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## PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package \| Pins | Package qty \| Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|---|---|---|---|---|---|---|---|---|---|
| TPS74501PBQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | Call TI | Level-1-260C-UNLIM | -40 to 125 | 1S36 |
| TPS74501PBQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | Call TI | Level-1-260C-UNLIM | -40 to 125 | 1S36 |
| TPS74501PCQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | Call TI | Level-1-260C-UNLIM | -40 to 125 | 1ZF6 |
| TPS74501PCQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | Call TI | Level-1-260C-UNLIM | -40 to 125 | 1ZF6 |
| TPS74501PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74501P |
| TPS74501PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74501P |
| TPS74501PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1S26 |
| TPS74501PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1S26 |
| TPS745105PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | Call TI | Level-1-260C-UNLIM | -40 to 125 | 1S66 |
| TPS745105PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | Call TI | Level-1-260C-UNLIM | -40 to 125 | 1S66 |
| TPS74510PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74510P |
| TPS74510PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74510P |
| TPS74510PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1S56 |
| TPS74510PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1S56 |
| TPS745115PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 745115 |
| TPS745115PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 745115 |
| TPS74511PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74511P |
| TPS74511PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74511P |
| TPS74511PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1S76 |
| TPS74511PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1S76 |
| TPS745125PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 745125 |
| TPS745125PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 745125 |
| TPS74512PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74512P |
| TPS74512PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74512P |
| TPS74512PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1S86 |
| TPS74512PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1S86 |
| TPS745135PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 745135 |
| TPS745135PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 745135 |
| TPS74513PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74513P |

| Orderable part number | Status (1) | Material type (2) | Package \| Pins | Package qty \| Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|---|---|---|---|---|---|---|---|---|---|
| TPS74513PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74513P |
| TPS74515PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74515P |
| TPS74515PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74515P |
| TPS74515PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1S96 |
| TPS74515PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1S96 |
| TPS74517PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74517P |
| TPS74517PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74517P |
| TPS74518PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74518P |
| TPS74518PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74518P |
| TPS74518PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SA6 |
| TPS74518PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SA6 |
| TPS74522PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SB6 |
| TPS74522PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SB6 |
| TPS74525PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74525P |
| TPS74525PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74525P |
| TPS74525PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SC6 |
| TPS74525PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SC6 |
| TPS74528PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SD6 |
| TPS74528PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SD6 |
| TPS74529PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SE6 |
| TPS74529PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SE6 |
| TPS74530PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74530P |
| TPS74530PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74530P |
| TPS74533PCQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1ZE6 |
| TPS74533PCQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1ZE6 |
| TPS74533PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74533P |
| TPS74533PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74533P |
| TPS74533PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SF6 |
| TPS74533PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1SF6 |
| TPS74534PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74534P |
| TPS74534PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74534P |

| Orderable part number | Status (1) | Material type (2) | Package \| Pins | Package qty \| Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|---|---|---|---|---|---|---|---|---|---|
| TPS74550PQWDRBRQ1 | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74550P |
| TPS74550PQWDRBRQ1.A | Active | Production | SON (DRB) \| 8 | 3000 \| LARGE T&R | Yes | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | 74550P |
| TPS74550PQWDRVRQ1 | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1T36 |
| TPS74550PQWDRVRQ1.A | Active | Production | WSON (DRV) \| 6 | 3000 \| LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | 1T36 |

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TPS745-Q1 :**

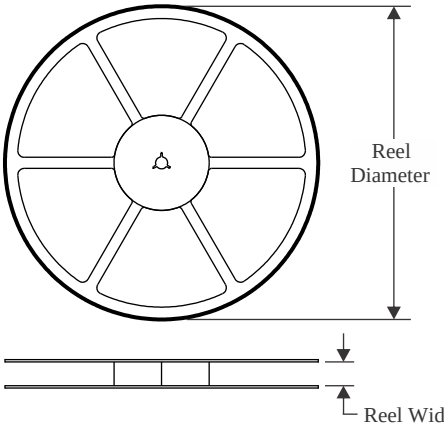
- Catalog : TPS745

NOTE: Qualified Version Definitions:

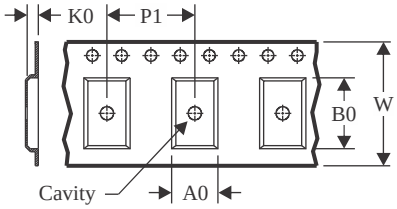
- Catalog - TI's standard catalog product

## TAPE AND REEL INFORMATION

**REEL DIMENSIONS**

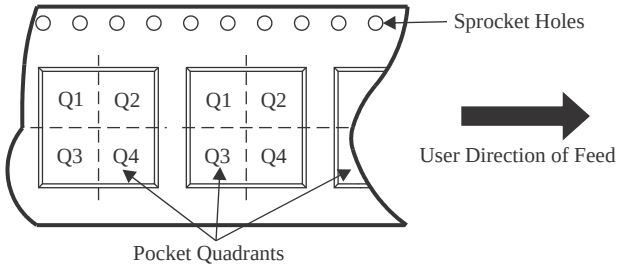



**TAPE DIMENSIONS**




| | |
|---|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

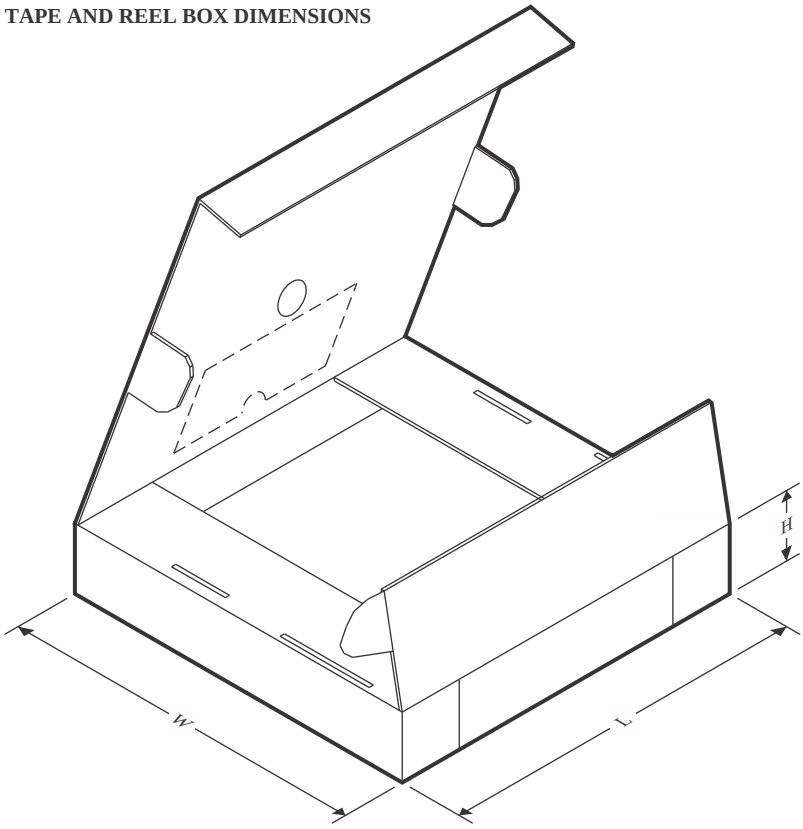



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| TPS74501PBQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74501PCQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74501PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74501PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS745105PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74510PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74510PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS745115PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74511PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74511PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS745125PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74512PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74512PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS745135PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74513PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74515PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| TPS74515PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74517PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74518PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74518PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74522PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74525PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74525PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74528PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74529PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74530PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74533PCQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74533PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74533PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |
| TPS74534PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74550PQWDRBRQ1 | SON | DRB | 8 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |
| TPS74550PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 180.0 | 8.4 | 2.2 | 2.2 | 1.2 | 4.0 | 8.0 | Q2 |

TAPE AND REEL BOX DIMENSIONS



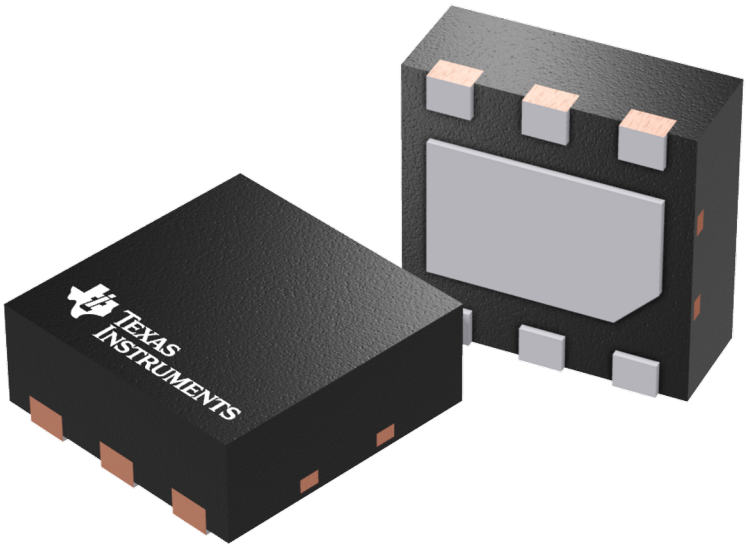

*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---|---|---|---|---|---|---|---|
| TPS74501PBQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74501PCQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74501PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74501PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS745105PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74510PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74510PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS745115PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74511PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74511PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS745125PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74512PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74512PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS745135PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74513PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74515PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74515PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74517PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---|---|---|---|---|---|---|---|
| TPS74518PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74518PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74522PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74525PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74525PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74528PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74529PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74530PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74533PCQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74533PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74533PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |
| TPS74534PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74550PQWDRBRQ1 | SON | DRB | 8 | 3000 | 367.0 | 367.0 | 35.0 |
| TPS74550PQWDRVRQ1 | WSON | DRV | 6 | 3000 | 200.0 | 183.0 | 25.0 |

# DRV 6 WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



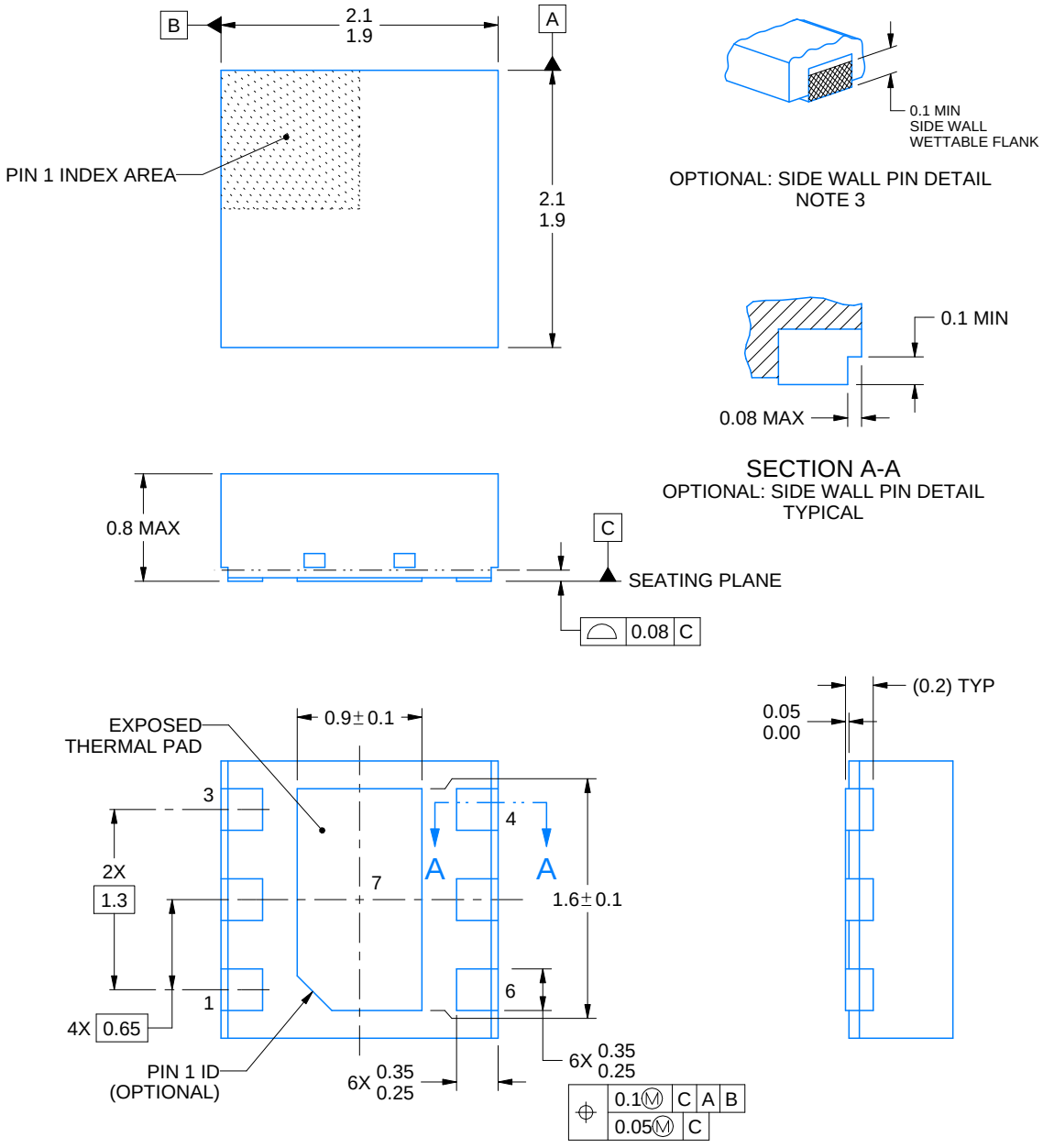

Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

# DRV0006C

# PACKAGE OUTLINE

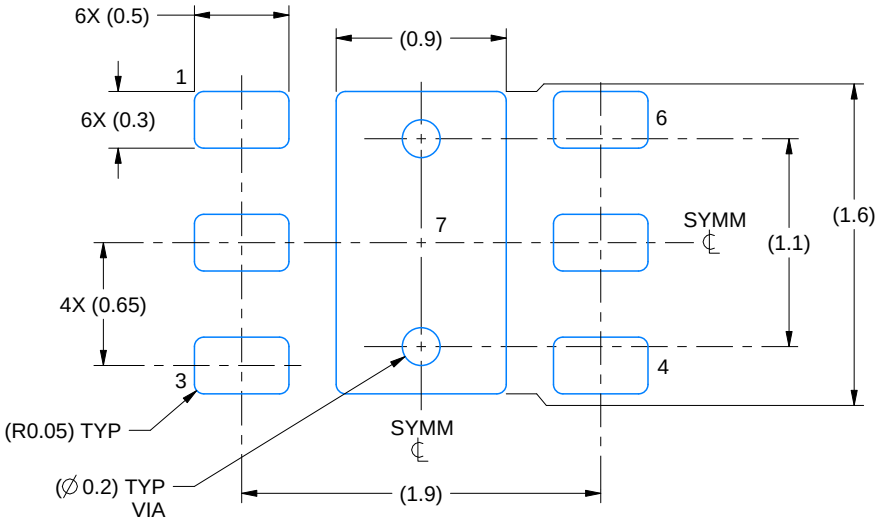
## WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

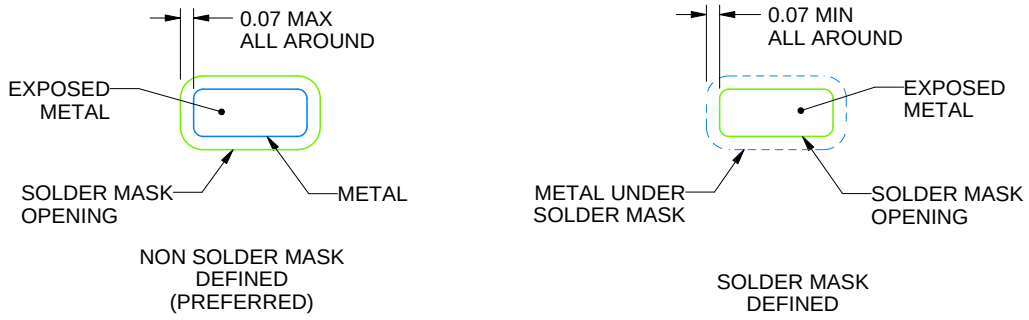



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Minimum 0.1 mm solder wetting on pin side wall. Available for wettable flank version only.




LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:25X

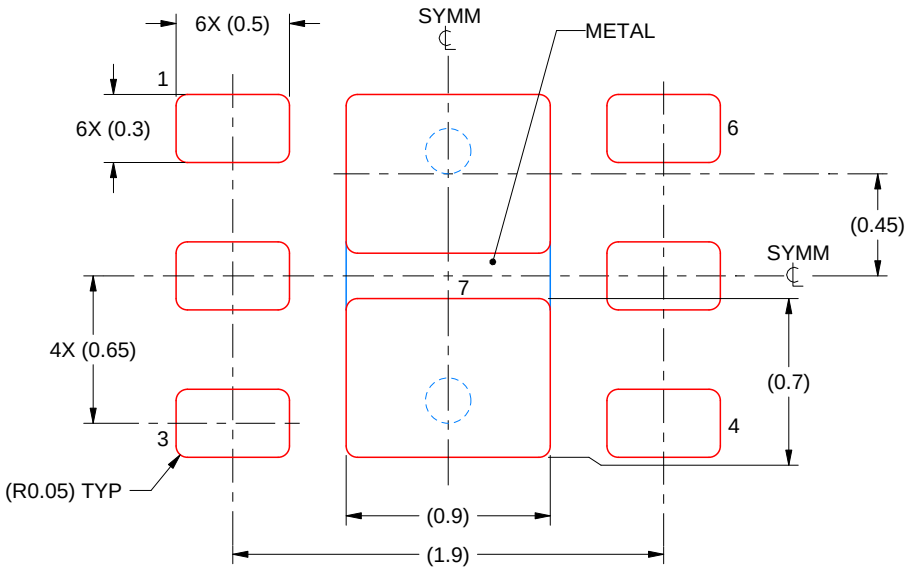



SOLDER MASK DETAILS

4223939/C 06/2026

NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.




SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7:
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4223939/C 06/2026

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

## GENERIC PACKAGE VIEW

# DRB 8

# VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD




Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

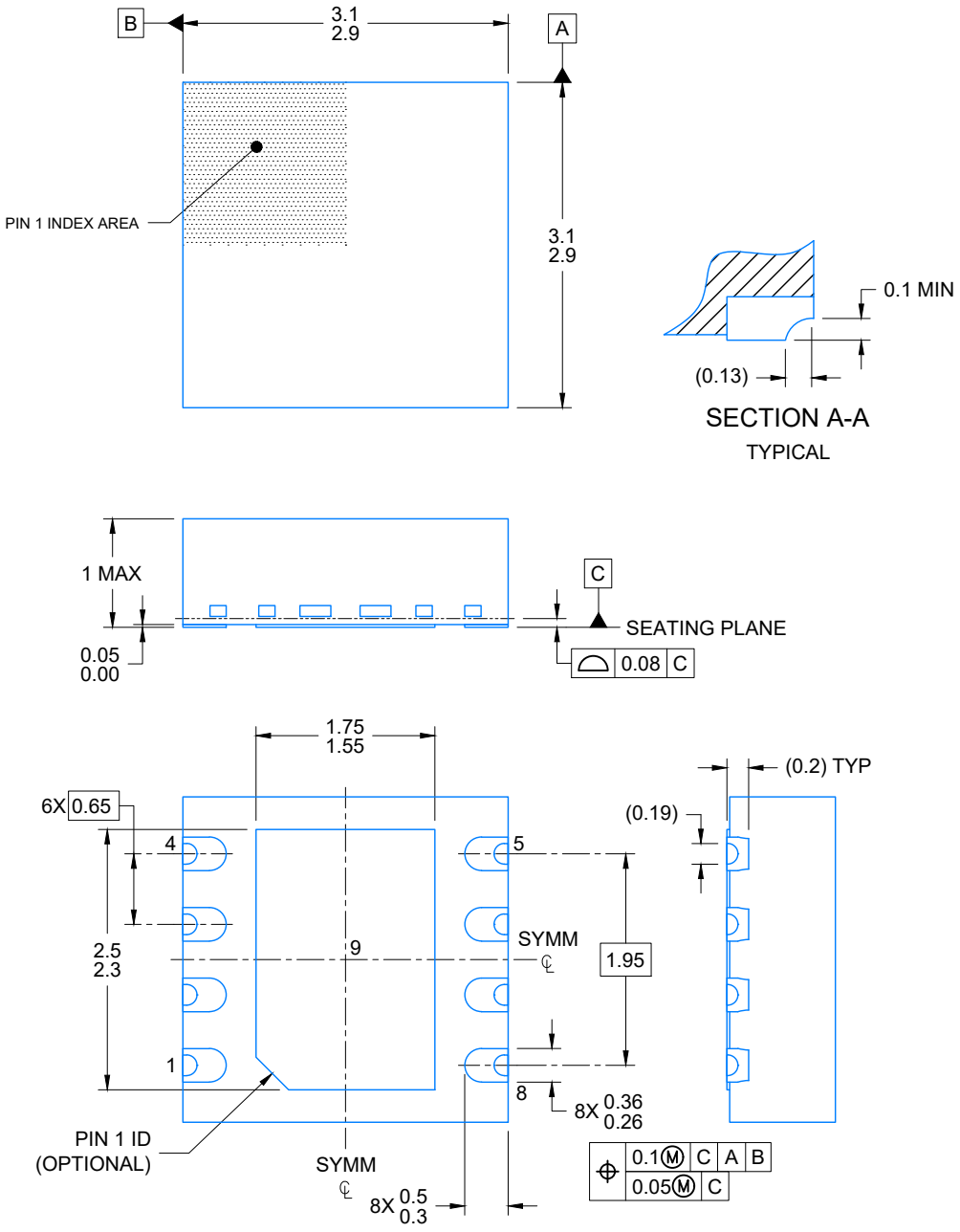
4203482/L

# PACKAGE OUTLINE

## DRB0008J

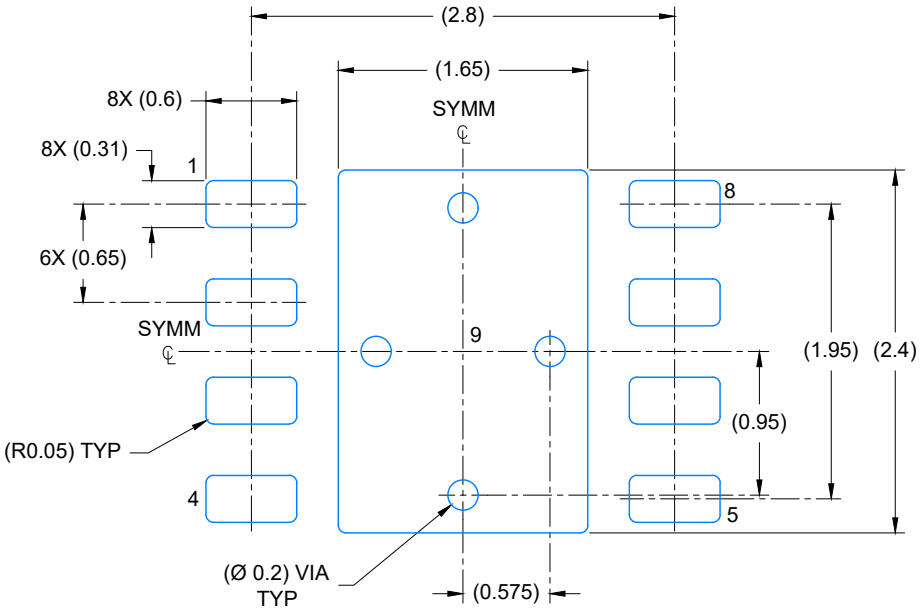
## VSON - 1 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD

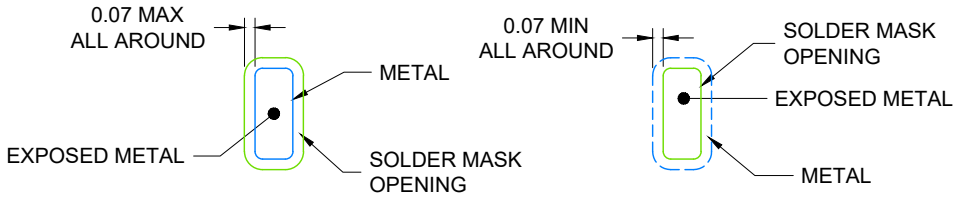



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.




LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X




NON- SOLDER MASK
DEFINED
(PREFERRED)

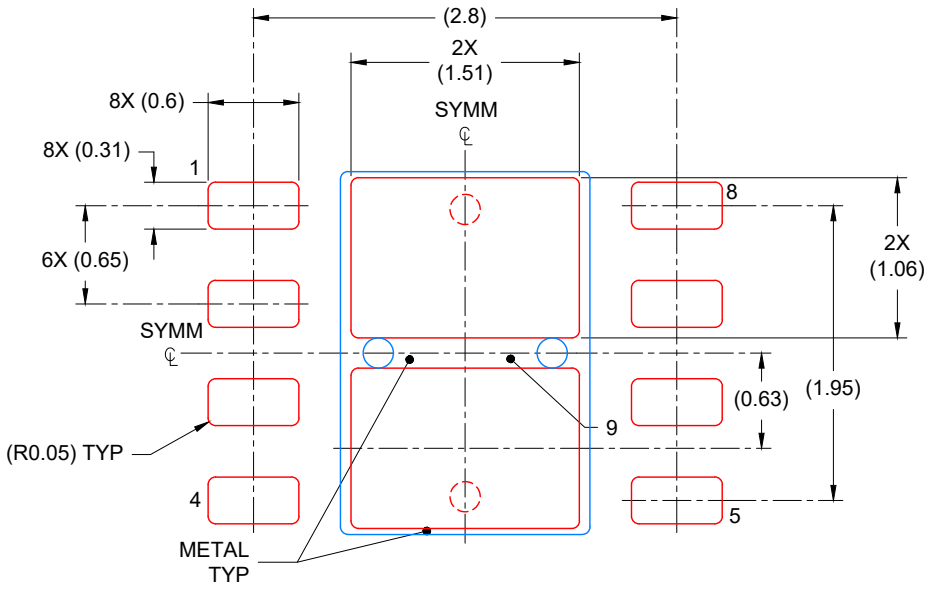
SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4225036/A 06/2019

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.




SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
81% PRINTED COVERAGE BY AREA
SCALE: 20X

4225036/A 06/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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Last updated 10/2025

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